



The following document contains information on Cypress products. Although the document is marked with the name “Spansion” and “Fujitsu”, the company that originally developed the specification, Cypress will continue to offer these products to new and existing customers.

Continuity of Specifications

There is no change to this document as a result of offering the device as a Cypress product. Any changes that have been made are the result of normal document improvements and are noted in the document history page, where supported. Future revisions will occur when appropriate, and changes will be noted in a document history page.

Continuity of Ordering Part Numbers

Cypress continues to support existing part numbers. To order these products, please use only the Ordering Part Numbers listed in this document.

For More Information

Please contact your local sales office for additional information about Cypress products and solutions.

About Cypress

Cypress (NASDAQ: CY) delivers high-performance, high-quality solutions at the heart of today’s most advanced embedded systems, from automotive, industrial and networking platforms to highly interactive consumer and mobile devices. With a broad, differentiated product portfolio that includes NOR flash memories, F-RAM™ and SRAM, Traveo™ microcontrollers, the industry’s only PSoC® programmable system-on-chip solutions, analog and PMIC Power Management ICs, CapSense® capacitive touch-sensing controllers, and Wireless BLE Bluetooth® Low-Energy and USB connectivity solutions, Cypress is committed to providing its customers worldwide with consistent innovation, best-in-class support and exceptional system value.

8-bit Microcontrollers

CMOS

F²MC-8FX MB95350L Series

MB95F352E/F352L/F353E/F353L/F354E/F354L

■ DESCRIPTION

MB95350L is a series of general-purpose, single-chip microcontrollers. In addition to a compact instruction set, the microcontrollers of this series contain a variety of peripheral resources.

Note: F²MC is the abbreviation of FUJITSU Flexible Microcontroller.

■ FEATURES

- F²MC-8FX CPU core
 - Instruction set optimized for controllers
 - Multiplication and division instructions
 - 16-bit arithmetic operations
 - Bit test branch instructions
 - Bit manipulation instructions, etc.
- Clock
 - Selectable main clock source
 - Main OSC clock (up to 16.25 MHz, maximum machine clock frequency: 8.125 MHz)
 - External clock (up to 32.5 MHz, maximum machine clock frequency: 16.25 MHz)
 - Main CR clock (1/8/10/12.5 MHz \pm 2%, maximum machine clock frequency: 12.5 MHz)
 - Selectable subclock source
 - Sub-OSC clock (32.768 kHz)
 - External clock (32.768 kHz)
 - Sub-CR clock (Typ: 100 kHz, Min: 50 kHz, Max: 200 kHz)
- Timer
 - 8/16-bit composite timer \times 2 channels
 - Time-base timer \times 1 channel
 - Watch prescaler \times 1 channel
- UART/SIO \times 1 channel (The channel can be used either as a UART/SIO channel or as an I²C channel.)
 - Alternative selection of UART/SIO
 - Full duplex double buffer
 - Capable of clock-asynchronous (UART) serial data transfer and clock-synchronous (SIO) serial data transfer

(Continued)

For the information for microcontroller supports, see the following website.

<http://edevic.fujitsu.com/micom/en-support/>

MB95350L Series

(Continued)

- I²C × 2 channels (One of the two channels can be used either as an I²C channel or as a UART/SIO channel.)
 - Supports Standard-mode and Fast-mode (400 kHz)
 - Built-in wake-up function
- LIN-UART
 - Full duplex double buffer
 - Capable of clock-synchronous serial data transfer and clock-asynchronous serial data transfer
- External interrupt × 6 channels
 - Interrupt by edge detection (rising edge, falling edge, and both edges can be selected)
 - Can be used to wake up the device from different low power consumption (standby) modes
- 8/10-bit A/D converter × 6 channels
 - 8-bit and 10-bit resolution can be chosen.
- Low power consumption (standby) modes
 - Stop mode
 - Sleep mode
 - Watch mode
 - Time-base timer mode
- I/O port
 - MB95F352L/F353L/F354L (maximum no. of I/O ports: 21)
 - General-purpose I/O ports (N-ch open drain) : 3
 - General-purpose I/O ports (CMOS I/O) : 18
 - MB95F352E/F353E/F354E (maximum no. of I/O ports: 22)
 - General-purpose I/O ports (N-ch open drain) : 3
 - General-purpose I/O ports (CMOS I/O) : 18
 - General-purpose input port (CMOS input) : 1
- On-chip debug
 - 1-wire serial control
 - Serial writing supported (asynchronous mode)
- Hardware/software watchdog timer
 - Built-in hardware watchdog timer
 - Built-in software watchdog timer
- Low-voltage detection reset and interrupt circuit
 - Built-in low-voltage detector
- Clock supervisor counter
 - Built-in clock supervisor counter function
- Programmable port input voltage level
 - CMOS input level / hysteresis input level
- Dual operation Flash memory
 - The erase/write operation and the read operation can be executed in different banks (upper bank/lower bank) simultaneously.
- Flash memory security function
 - Protects the content of the Flash memory

MB95350L Series

■ PRODUCT LINE-UP

Part number	MB95F352E	MB95F353E	MB95F354E	MB95F352L	MB95F353L	MB95F354L
Parameter						
Type	Flash memory product					
Clock supervisor counter	It supervises the main clock oscillation.					
Program ROM capacity	8 Kbyte	12 Kbyte	20 Kbyte	8 Kbyte	12 Kbyte	20 Kbyte
RAM capacity	240 bytes	496 bytes	496 bytes	240 bytes	496 bytes	496 bytes
Low-voltage detection reset	Yes			No		
Reset input	Selected through software			Dedicated		
CPU functions	Number of basic instructions : 136 Instruction bit length : 8 bits Instruction length : 1 to 3 bytes Data bit length : 1, 8 and 16 bits Minimum instruction execution time : 61.5 ns (with machine clock = 16.25 MHz) Interrupt processing time : 0.6 μs (with machine clock = 16.25 MHz)					
General-purpose I/O	I/O ports (Max): 22 CMOS I/O: 18 N-ch open drain: 3 CMOS input: 1			I/O ports (Max): 21 CMOS I/O: 18 N-ch open drain: 3		
Time-base timer	Interrupt cycle: 0.256 ms to 8.3 s (when external clock = 4 MHz)					
Hardware/software watchdog timer	Reset generation cycle - Main oscillation clock at 10 MHz: 105 ms (Min) The sub-CR clock can be used as the source clock of the hardware watchdog timer.					
Wild register	It can be used to replace three bytes of data.					
LIN-UART	A wide range of communication speeds can be selected by a dedicated reload timer. Clock-synchronous serial data transfer and clock-asynchronous serial data transfer is enabled. The LIN function can be used as a LIN master or a LIN slave.					
8/10-bit A/D converter	6 channels 8-bit resolution and 10-bit resolution can be chosen.					
8/16-bit composite timer	2 channels The timer can be configured as an "8-bit timer x 2 channels" or a "16-bit timer x 1 channel". It has built-in timer function, PWC function, PWM function and input capture function. Count clock: it can be selected from internal clocks (seven types) and external clocks. It can output square wave.					
External interrupt	6 channels Interrupt by edge detection (The rising edge, falling edge, or both edges can be selected.) It can be used to wake up the device from different standby modes.					
On-chip debug	1-wire serial control It supports serial writing. (asynchronous mode)					

(Continued)

MB95350L Series

(Continued)

Part number	MB95F352E	MB95F353E	MB95F354E	MB95F352L	MB95F353L	MB95F354L
Parameter						
UART/SIO	1 channel (The channel can be used either as a UART/SIO channel or as an I ² C channel.) Data transfer with UART/SIO is enabled. It has a full duplex double buffer, variable data length (5/6/7/8 bits), a built-in baud rate generator and an error detection function. It uses the NRZ type transfer format. LSB-first data transfer and MSB-first data transfer are available to use. Clock-asynchronous (UART) serial data transfer and clock-synchronous (SIO) serial data transfer is enabled.					
I ² C	2 channels (One of the two channels can be used either as an I ² C channel or as a UART/SIO channel.) Master/slave transmission and receiving It has the following functions: <ul style="list-style-type: none"> • bus error function • arbitration function • transmission direction detection function • wake-up function • functions of generating and detecting repeated START conditions. 					
Watch prescaler	Eight different time intervals can be selected.					
Flash memory	It supports automatic programming, Embedded Algorithm, write/erase/erase-suspend/erase-resume commands. It has a flag indicating the completion of the operation of Embedded Algorithm. Number of write/erase cycles: 100000 Data retention time: 20 years Flash security feature for protecting the content of the Flash memory					
Standby mode	Sleep mode, stop mode, watch mode, time-base timer mode					
Package	FPT-24P-M34 FPT-24P-M10 LCC-32P-M19					

■ PACKAGES AND CORRESPONDING PRODUCTS

Part number Package	MB95F352E	MB95F353E	MB95F354E	MB95F352L	MB95F353L	MB95F354L
FPT-24P-M34	○	○	○	○	○	○
FPT-24P-M10	○	○	○	○	○	○
LCC-32P-M19	○	○	○	○	○	○

○: Available

■ DIFFERENCES AMONG PRODUCTS AND NOTES ON PRODUCT SELECTION

- Current consumption

When using the on-chip debug function, take account of the current consumption of flash erase/write.

For details of current consumption, see “■ ELECTRICAL CHARACTERISTICS”.

- Package

For details of information on each package, see “■ PACKAGES AND CORRESPONDING PRODUCTS” and “■ PACKAGE DIMENSIONS”.

- Operating voltage

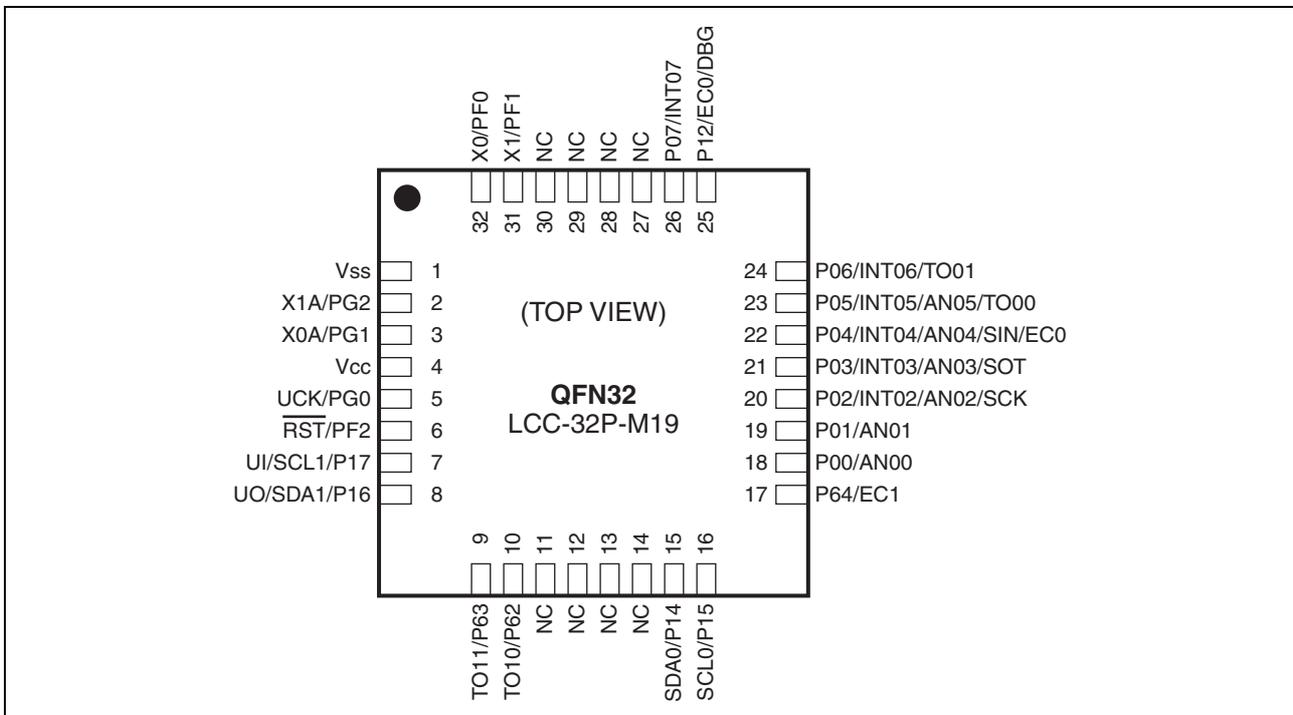
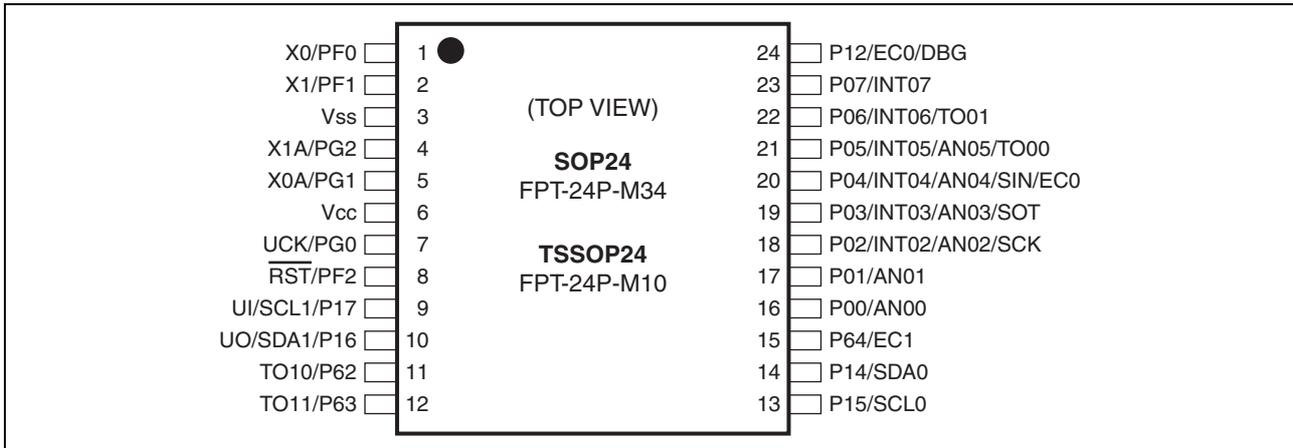
The operating voltage varies, depending on whether the on-chip debug function is used or not.

For details of the operating voltage, see “■ ELECTRICAL CHARACTERISTICS”.

- On-chip debug function

The on-chip debug function requires that V_{CC} , V_{SS} and one serial wire be connected to an evaluation tool.

■ PIN ASSIGNMENT



MB95350L Series

■ PIN DESCRIPTION (24-pin MCU)

Pin no.	Pin name	I/O circuit type*	Function
1	PF0	B	General-purpose I/O port
	X0		Main clock input oscillation pin
2	PF1	B	General-purpose I/O port
	X1		Main clock I/O oscillation pin
3	V _{ss}	—	Power supply pin (GND)
4	PG2	C	General-purpose I/O port
	X1A		Subclock I/O oscillation pin
5	PG1	C	General-purpose I/O port
	X0A		Subclock input oscillation pin
6	V _{cc}	—	Power supply pin
7	PG0	G	General-purpose I/O port
	UCK		UART/SIO clock pin
8	PF2	A	General-purpose input port
	$\overline{\text{RST}}$		Reset pin Dedicated reset pin on MB95F352L/F353L/F354L
9	P17	J	General-purpose I/O port
	SCL1		I ² C ch. 1 clock I/O pin
	UI		UART/SIO data input pin
10	P16	J	General-purpose I/O port
	SDA1		I ² C ch. 1 data I/O pin
	UO		UART/SIO data output pin
11	P62	D	General-purpose I/O port High-current pin
	TO10		8/16-bit composite timer ch. 1 output pin
12	P63	D	General-purpose I/O port High-current pin
	TO11		8/16-bit composite timer ch. 1 output pin
13	P15	I	General-purpose I/O port
	SCL0		I ² C ch. 0 clock I/O pin
14	P14	I	General-purpose I/O port
	SDA0		I ² C ch. 0 data I/O pin
15	P64	D	General-purpose I/O port
	EC1		8/16-bit composite timer ch. 1 clock input pin
16	P00	E	General-purpose I/O port
	AN00		A/D converter analog input pin

(Continued)

(Continued)

Pin no.	Pin name	I/O circuit type*	Function
17	P01	E	General-purpose I/O port
	AN01		A/D converter analog input pin
18	P02	E	General-purpose I/O port
	INT02		External interrupt input pin
	AN02		A/D converter analog input pin
	SCK		LIN-UART clock I/O pin
19	P03	E	General-purpose I/O port
	INT03		External interrupt input pin
	AN03		A/D converter analog input pin
	SOT		LIN-UART data output pin
20	P04	F	General-purpose I/O port
	INT04		External interrupt input pin
	AN04		A/D converter analog input pin
	SIN		LIN-UART data input pin
	EC0		8/16-bit composite timer ch. 0 clock input pin
21	P05	E	General-purpose I/O port High-current pin
	INT05		External interrupt input pin
	AN05		A/D converter analog input pin
	TO00		8/16-bit composite timer ch. 0 output pin
22	P06	G	General-purpose I/O port High-current pin
	INT06		External interrupt input pin
	TO01		8/16-bit composite timer ch. 0 output pin
23	P07	G	General-purpose I/O port
	INT07		External interrupt input pin
24	P12	H	General-purpose I/O port
	EC0		8/16-bit composite timer ch. 0 clock input pin
	DBG		DBG input pin

*: For the I/O circuit types, see “■ I/O CIRCUIT TYPE”.

MB95350L Series

■ PIN DESCRIPTION (32-pin MCU)

Pin no.	Pin name	I/O circuit type*	Function
1	V _{SS}	—	Power supply pin (GND)
2	PG2	C	General-purpose I/O port
	X1A		Subclock I/O oscillation pin
3	PG1	C	General-purpose I/O port
	X0A		Subclock input oscillation pin
4	V _{CC}	—	Power supply pin
5	PG0	G	General-purpose I/O port
	UCK		UART/SIO clock pin
6	PF2	A	General-purpose input port
	$\overline{\text{RST}}$		Reset pin Dedicated reset pin on MB95F352L/F353L/F354L
7	P17	J	General-purpose I/O port
	SCL1		I ² C ch. 1 clock I/O pin
	UI		UART/SIO data input pin
8	P16	J	General-purpose I/O port
	SDA1		I ² C ch. 1 data I/O pin
	UO		UART/SIO data output pin
9	P63	D	General-purpose I/O port High-current pin
	TO11		8/16-bit composite timer ch. 1 output pin
10	P62	D	General-purpose I/O port High-current pin
	TO10		8/16-bit composite timer ch. 1 output pin
11	NC	—	It is an internally connected pin. Always leave it unconnected.
12	NC	—	It is an internally connected pin. Always leave it unconnected.
13	NC	—	It is an internally connected pin. Always leave it unconnected.
14	NC	—	It is an internally connected pin. Always leave it unconnected.
15	P14	I	General-purpose I/O port
	SDA0		I ² C ch. 0 data I/O pin
16	P15	I	General-purpose I/O port
	SCL0		I ² C ch. 0 clock I/O pin
17	P64	D	General-purpose I/O port
	EC1		8/16-bit composite timer ch. 1 clock input pin
18	P00	E	General-purpose I/O port
	AN00		A/D converter analog input pin

(Continued)

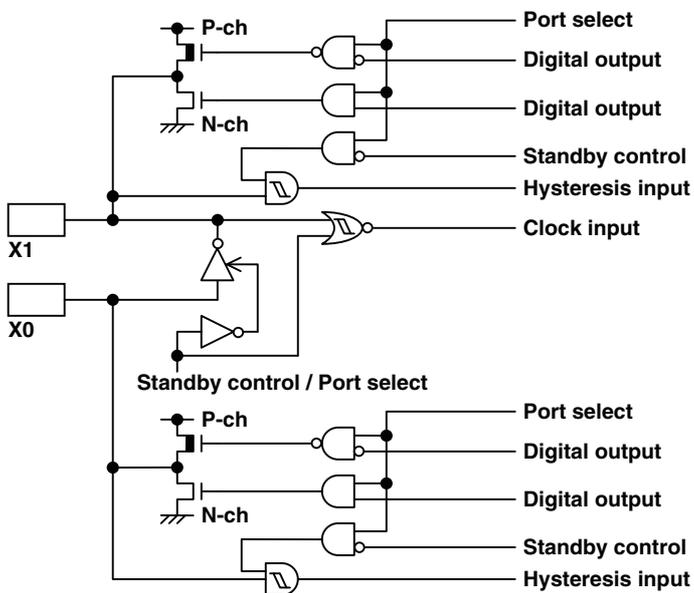
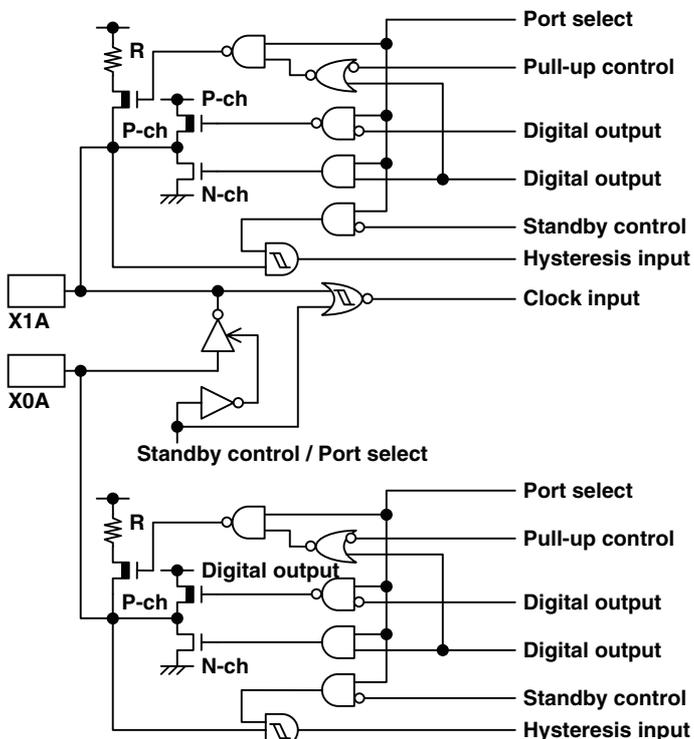
(Continued)

Pin no.	Pin name	I/O circuit type*	Function
19	P01	E	General-purpose I/O port
	AN01		A/D converter analog input pin
20	P02	E	General-purpose I/O port
	INT02		External interrupt input pin
	AN02		A/D converter analog input pin
	SCK		LIN-UART clock I/O pin
21	P03	E	General-purpose I/O port
	INT03		External interrupt input pin
	AN03		A/D converter analog input pin
	SOT		LIN-UART data output pin
22	P04	F	General-purpose I/O port
	INT04		External interrupt input pin
	AN04		A/D converter analog input pin
	SIN		LIN-UART data input pin
	EC0		8/16-bit composite timer ch. 0 clock input pin
23	P05	E	General-purpose I/O port High-current pin
	INT05		External interrupt input pin
	AN05		A/D converter analog input pin
	TO00		8/16-bit composite timer ch. 0 output pin
24	P06	G	General-purpose I/O port High-current pin
	INT06		External interrupt input pin
	TO01		8/16-bit composite timer ch. 0 output pin
25	P12	H	General-purpose I/O port
	EC0		8/16-bit composite timer ch. 0 clock input pin
	DBG		DBG input pin
26	P07	G	General-purpose I/O port
	INT07		External interrupt input pin
27	NC	—	It is an internally connected pin. Always leave it unconnected.
28	NC	—	It is an internally connected pin. Always leave it unconnected.
29	NC	—	It is an internally connected pin. Always leave it unconnected.
30	NC	—	It is an internally connected pin. Always leave it unconnected.
31	PF1	B	General-purpose I/O port
	X1		Main clock I/O oscillation pin
32	PF0	B	General-purpose I/O port
	X0		Main clock input oscillation pin

*: For the I/O circuit types, see “■ I/O CIRCUIT TYPE”.

MB95350L Series

■ I/O CIRCUIT TYPE

Type	Circuit	Remarks
A		<ul style="list-style-type: none"> • Hysteresis input • Reset input
B		<ul style="list-style-type: none"> • Oscillation circuit • High-speed side Feedback resistance: approx. 1 MΩ • CMOS output • Hysteresis input
C		<ul style="list-style-type: none"> • Oscillation circuit • Low-speed side Feedback resistance: approx. 10 MΩ • CMOS output • Hysteresis input • Pull-up control available

(Continued)

Type	Circuit	Remarks
D		<ul style="list-style-type: none"> • CMOS output • Hysteresis input
E		<ul style="list-style-type: none"> • CMOS output • Hysteresis input • Pull-up control available
F		<ul style="list-style-type: none"> • CMOS output • Hysteresis input • CMOS input • Pull-up control available
G		<ul style="list-style-type: none"> • CMOS output • Hysteresis input • Pull-up control available
H		<ul style="list-style-type: none"> • N-ch open drain output • Hysteresis input

(Continued)

MB95350L Series

(Continued)

Type	Circuit	Remarks
I	<p>The circuit diagram for Type I shows a rectangular block connected to the gates of an N-channel MOSFET and a CMOS input. The N-channel MOSFET's drain is connected to a digital output. The CMOS input and a hysteresis input are connected to the gates of a CMOS input and a hysteresis input, respectively. A standby control signal is connected to the gates of both the CMOS input and the hysteresis input.</p>	<ul style="list-style-type: none"> • N-ch open drain output • Hysteresis input • CMOS input
J	<p>The circuit diagram for Type J shows a rectangular block connected to the gates of a P-channel MOSFET, an N-channel MOSFET, and a CMOS input. The P-channel MOSFET's drain is connected to an I²C mode control digital output. The N-channel MOSFET's drain is connected to a digital output. The CMOS input and a hysteresis input are connected to the gates of a CMOS input and a hysteresis input, respectively. A standby control signal is connected to the gates of both the CMOS input and the hysteresis input.</p>	<ul style="list-style-type: none"> • CMOS output • Hysteresis input • CMOS input • N-ch open drain output in I²C mode

■ NOTES ON DEVICE HANDLING

• Preventing latch-ups

When using the device, ensure that the voltage applied does not exceed the maximum voltage rating.

In a CMOS IC, if a voltage higher than V_{CC} or a voltage lower than V_{SS} is applied to an input/output pin that is neither a medium-withstand voltage pin nor a high-withstand voltage pin, or if a voltage out of the rating range of power supply voltage mentioned in "1. Absolute Maximum Ratings" of "■ ELECTRICAL CHARACTERISTICS" is applied to the V_{CC} pin or the V_{SS} pin, a latch-up may occur.

When a latch-up occurs, power supply current increases significantly, which may cause a component to be thermally destroyed.

• Stabilizing supply voltage

Supply voltage must be stabilized.

A malfunction may occur when power supply voltage fluctuates rapidly even though the fluctuation is within the guaranteed operating range of the V_{CC} power supply voltage.

As a rule of voltage stabilization, suppress voltage fluctuation so that the fluctuation in V_{CC} ripple (p-p value) at the commercial frequency (50 Hz/60 Hz) does not exceed 10% of the standard V_{CC} value, and the transient fluctuation rate does not exceed 0.1 V/ms at a momentary fluctuation such as switching the power supply.

• Notes on using the external clock

When an external clock is used, oscillation stabilization wait time is required for power-on reset, wake-up from subclock mode or stop mode.

■ PIN CONNECTION

• Treatment of unused pins

If an unused input pin is left unconnected, a component may be permanently damaged due to malfunctions or latch-ups. Always pull up or pull down an unused input pin through a resistor of at least 2 k Ω . Set an unused input/output pin to the output state and leave it unconnected, or set it to the input state and treat it the same as an unused input pin. If there is an unused output pin, leave it unconnected.

• Power supply pins

To reduce unnecessary electro-magnetic emission, prevent malfunctions of strobe signals due to an increase in the ground level, and conform to the total output current standard, always connect the V_{CC} pin and the V_{SS} pin to the power supply and ground outside the device. In addition, connect the current supply source to the V_{CC} pin and the V_{SS} pin with low impedance.

It is also advisable to connect a ceramic capacitor of approximately 0.1 μ F as a bypass capacitor between the V_{CC} pin and the V_{SS} pin at a location close to this device.

• DBG pin

Connect the DBG pin directly to an external pull-up resistor.

To prevent the device from unintentionally entering the debug mode due to noise, minimize the distance between the DBG pin and the V_{CC} or V_{SS} pin when designing the layout of the printed circuit board.

The DBG pin should not stay at "L" level after power-on until the reset is released.

• \overline{RST} pin

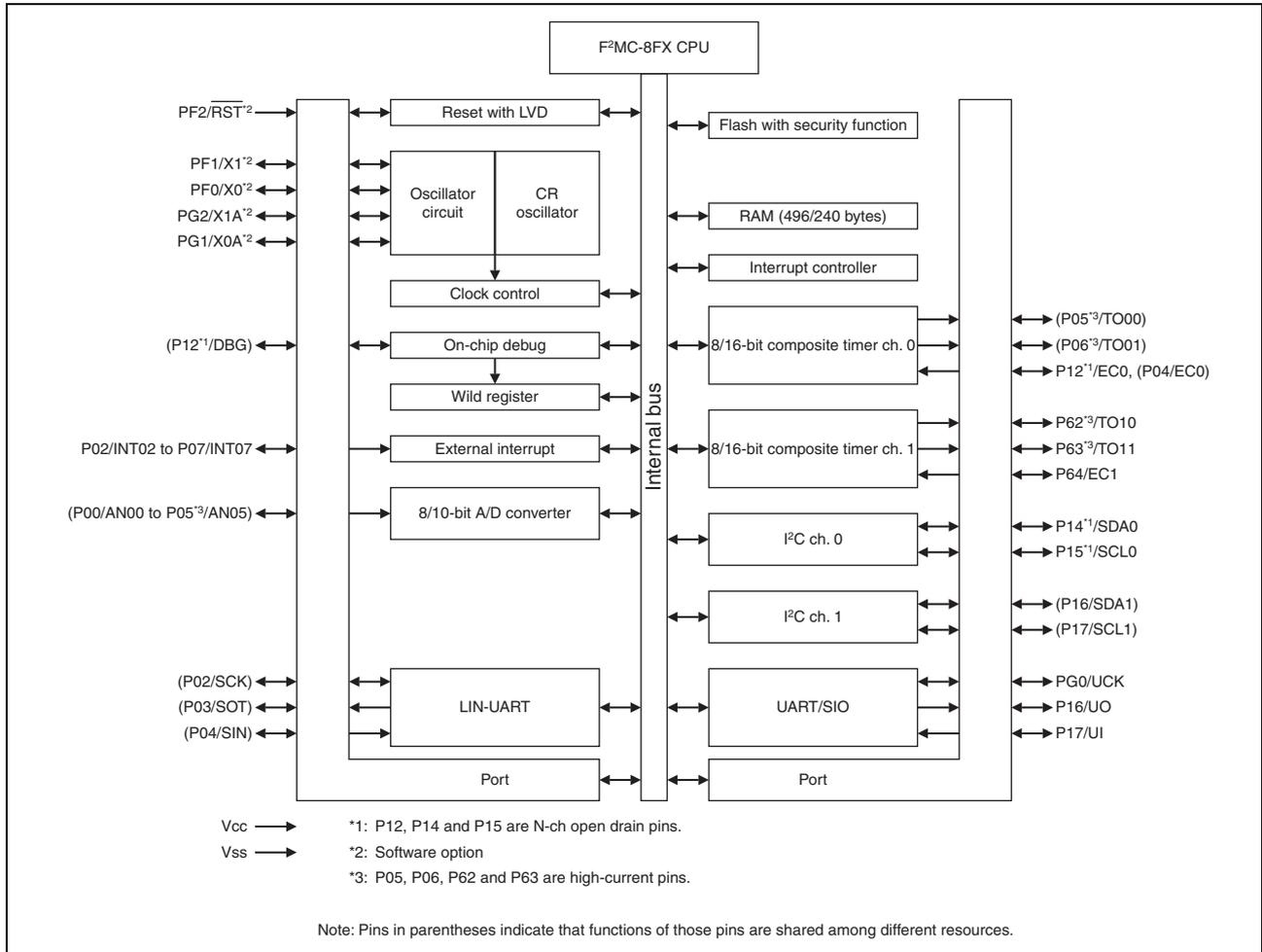
Connect the \overline{RST} pin directly to an external pull-up resistor.

To prevent the device from unintentionally entering the reset mode due to noise, minimize the distance between the \overline{RST} pin and the V_{CC} or V_{SS} pin when designing the layout of the printed circuit board.

The PF2/ \overline{RST} pin functions as the reset input pin after power-on. The RSTEN bit in the SYSC register is used to switch the pin functions, the reset input function and the general-purpose I/O port function, of the PF2/ \overline{RST} pin. However, only on MB95F352E/F353E/F354E can the pin functions be changed.

MB95350L Series

■ BLOCK DIAGRAM



■ CPU CORE

• Memory Space

The memory space of the MB95350L Series is 64 Kbyte in size, and consists of an I/O area, a data area, and a program area. The memory space includes areas intended for specific purposes such as general-purpose registers and a vector table. The memory maps of the MB95350L Series are shown below.

• Memory Maps

MB95F352E/F352L		MB95F353E/F353L		MB95F354E/F354L	
0000 _H	I/O	0000 _H	I/O	0000 _H	I/O
0080 _H	Access prohibited	0080 _H	Access prohibited	0080 _H	Access prohibited
0090 _H	RAM 240 bytes	0090 _H	RAM 496 bytes	0090 _H	RAM 496 bytes
0100 _H	Register	0100 _H	Register	0100 _H	Register
0180 _H		0200 _H		0200 _H	
	Access prohibited	0280 _H	Access prohibited	0280 _H	Access prohibited
0F80 _H	Extended I/O	0F80 _H	Extended I/O	0F80 _H	Extended I/O
1000 _H	Access prohibited	1000 _H	Access prohibited	1000 _H	Access prohibited
B000 _H	Flash 4 Kbyte	B000 _H	Flash 4 Kbyte	B000 _H	Flash 20 Kbyte
C000 _H	Access prohibited	C000 _H	Access prohibited		
F000 _H	Flash 4 Kbyte	E000 _H	Flash 8 Kbyte		
FFFF _H		FFFF _H		FFFF _H	

MB95350L Series

■ I/O MAP

Address	Register abbreviation	Register name	R/W	Initial value
0000 _H	PDR0	Port 0 data register	R/W	00000000 _B
0001 _H	DDR0	Port 0 direction register	R/W	00000000 _B
0002 _H	PDR1	Port 1 data register	R/W	00000000 _B
0003 _H	DDR1	Port 1 direction register	R/W	00000000 _B
0004 _H	—	(Disabled)	—	—
0005 _H	WATR	Oscillation stabilization wait time setting register	R/W	11111111 _B
0006 _H	—	(Disabled)	—	—
0007 _H	SYCC	System clock control register	R/W	0000X011 _B
0008 _H	STBC	Standby control register	R/W	00000XXX _B
0009 _H	RSRR	Reset source register	R/W	XXXXXXXX _B
000A _H	TBTC	Time-base timer control register	R/W	00000000 _B
000B _H	WPCR	Watch prescaler control register	R/W	00000000 _B
000C _H	WDTC	Watchdog timer control register	R/W	00XX0000 _B
000D _H	SYCC2	System clock control register 2	R/W	XX100011 _B
000E _H to 0015 _H	—	(Disabled)	—	—
0016 _H	PDR6	Port 6 data register	R/W	00000000 _B
0017 _H	DDR6	Port 6 direction register	R/W	00000000 _B
0018 _H to 0027 _H	—	(Disabled)	—	—
0028 _H	PDRF	Port F data register	R/W	00000000 _B
0029 _H	DDRF	Port F direction register	R/W	00000000 _B
002A _H	PDRG	Port G data register	R/W	00000000 _B
002B _H	DDRG	Port G direction register	R/W	00000000 _B
002C _H	PUL0	Port 0 pull-up register	R/W	00000000 _B
002D _H to 0034 _H	—	(Disabled)	—	—
0035 _H	PULG	Port G pull-up register	R/W	00000000 _B
0036 _H	T01CR1	8/16-bit composite timer 01 status control register 1 ch. 0	R/W	00000000 _B
0037 _H	T00CR1	8/16-bit composite timer 00 status control register 1 ch. 0	R/W	00000000 _B
0038 _H	T11CR1	8/16-bit composite timer 11 status control register 1 ch. 1	R/W	00000000 _B
0039 _H	T10CR1	8/16-bit composite timer 10 status control register 1 ch. 1	R/W	00000000 _B
003A _H to 0048 _H	—	(Disabled)	—	—
0049 _H	EIC10	External interrupt circuit control register ch. 2/ch. 3	R/W	00000000 _B
004A _H	EIC20	External interrupt circuit control register ch. 4/ch. 5	R/W	00000000 _B
004B _H	EIC30	External interrupt circuit control register ch. 6/ch. 7	R/W	00000000 _B

(Continued)

MB95350L Series

Address	Register abbreviation	Register name	R/W	Initial value
004C _H , 004D _H	—	(Disabled)	—	—
004E _H	LVDR	LVD reset voltage selection ID register	R/W	00000000 _B
004F _H	LVDC	LVD interrupt control register	R/W	X000000X _B
0050 _H	SCR	LIN-UART serial control register	R/W	00000000 _B
0051 _H	SMR	LIN-UART serial mode register	R/W	00000000 _B
0052 _H	SSR	LIN-UART serial status register	R/W	00001000 _B
0053 _H	RDR/TDR	LIN-UART receive/transmit data register	R/W	00000000 _B
0054 _H	ESCR	LIN-UART extended status control register	R/W	00000100 _B
0055 _H	ECCR	LIN-UART extended communication control register	R/W	000000XX _B
0056 _H	SMC10	UART/SIO serial mode control register 1 ch. 0	R/W	00000000 _B
0057 _H	SMC20	UART/SIO serial mode control register 2 ch. 0	R/W	00100000 _B
0058 _H	SSR0	UART/SIO serial status and data register ch. 0	R/W	00000001 _B
0059 _H	TDR0	UART/SIO serial output data register ch. 0	R/W	00000000 _B
005A _H	RDR0	UART/SIO serial input data register ch. 0	R	00000000 _B
005B _H to 005F _H	—	(Disabled)	—	—
0060 _H	IBCR00	I ² C bus control register 0 ch. 0	R/W	00000000 _B
0061 _H	IBCR10	I ² C bus control register 1 ch. 0	R/W	00000000 _B
0062 _H	IBSR0	I ² C bus status register ch. 0	R	00000000 _B
0063 _H	IDDR0	I ² C data register ch. 0	R/W	00000000 _B
0064 _H	IAAR0	I ² C address register ch. 0	R/W	00000000 _B
0065 _H	ICCR0	I ² C clock control register ch. 0	R/W	00000000 _B
0066 _H	IBCR01	I ² C bus control register 0 ch. 1	R/W	00000000 _B
0067 _H	IBCR11	I ² C bus control register 1 ch. 1	R/W	00000000 _B
0068 _H	IBSR1	I ² C bus status register ch. 1	R	00000000 _B
0069 _H	IDDR1	I ² C data register ch. 1	R/W	00000000 _B
006A _H	IAAR1	I ² C address register ch. 1	R/W	00000000 _B
006B _H	ICCR1	I ² C clock control register ch. 1	R/W	00000000 _B
006C _H	ADC1	8/10-bit A/D converter control register 1	R/W	00000000 _B
006D _H	ADC2	8/10-bit A/D converter control register 2	R/W	00000000 _B
006E _H	ADDH	8/10-bit A/D converter data register (upper)	R/W	00000000 _B
006F _H	ADDL	8/10-bit A/D converter data register (lower)	R/W	00000000 _B
0070 _H	—	(Disabled)	—	—
0071 _H	FSR2	Flash memory status register 2	R/W	00000000 _B
0072 _H	FSR	Flash memory status register	R/W	000X0000 _B
0073 _H	SWRE0	Flash memory sector write control register 0	R/W	00000000 _B
0074 _H	FSR3	Flash memory status register 3	R	00000000 _B

(Continued)

MB95350L Series

Address	Register abbreviation	Register name	R/W	Initial value
0075 _H	—	(Disabled)	—	—
0076 _H	WREN	Wild register address compare enable register	R/W	00000000 _B
0077 _H	WROR	Wild register data test setting register	R/W	00000000 _B
0078 _H	—	Mirror of register bank pointer (RP) and mirror of direct bank pointer (DP)	—	—
0079 _H	ILR0	Interrupt level setting register 0	R/W	11111111 _B
007A _H	ILR1	Interrupt level setting register 1	R/W	11111111 _B
007B _H	ILR2	Interrupt level setting register 2	R/W	11111111 _B
007C _H	ILR3	Interrupt level setting register 3	R/W	11111111 _B
007D _H	ILR4	Interrupt level setting register 4	R/W	11111111 _B
007E _H	ILR5	Interrupt level setting register 5	R/W	11111111 _B
007F _H	—	(Disabled)	—	—
0F80 _H	WRARH0	Wild register address setting register (upper) ch. 0	R/W	00000000 _B
0F81 _H	WRARL0	Wild register address setting register (lower) ch. 0	R/W	00000000 _B
0F82 _H	WRDR0	Wild register data setting register ch. 0	R/W	00000000 _B
0F83 _H	WRARH1	Wild register address setting register (upper) ch. 1	R/W	00000000 _B
0F84 _H	WRARL1	Wild register address setting register (lower) ch. 1	R/W	00000000 _B
0F85 _H	WRDR1	Wild register data setting register ch. 1	R/W	00000000 _B
0F86 _H	WRARH2	Wild register address setting register (upper) ch. 2	R/W	00000000 _B
0F87 _H	WRARL2	Wild register address setting register (lower) ch. 2	R/W	00000000 _B
0F88 _H	WRDR2	Wild register data setting register ch. 2	R/W	00000000 _B
0F89 _H to 0F91 _H	—	(Disabled)	—	—
0F92 _H	T01CR0	8/16-bit composite timer 01 status control register 0 ch. 0	R/W	00000000 _B
0F93 _H	T00CR0	8/16-bit composite timer 00 status control register 0 ch. 0	R/W	00000000 _B
0F94 _H	T01DR	8/16-bit composite timer 01 data register ch. 0	R/W	00000000 _B
0F95 _H	T00DR	8/16-bit composite timer 00 data register ch. 0	R/W	00000000 _B
0F96 _H	TMCR0	8/16-bit composite timer 00/01 timer mode control register ch. 0	R/W	00000000 _B
0F97 _H	T11CR0	8/16-bit composite timer 11 status control register 0 ch. 1	R/W	00000000 _B
0F98 _H	T10CR0	8/16-bit composite timer 10 status control register 0 ch. 1	R/W	00000000 _B
0F99 _H	T11DR	8/16-bit composite timer 11 data register ch. 1	R/W	00000000 _B
0F9A _H	T10DR	8/16-bit composite timer 10 data register ch. 1	R/W	00000000 _B
0F9B _H	TMCR1	8/16-bit composite timer 10/11 timer mode control register ch. 1	R/W	00000000 _B
0F9C _H to 0FBB _H	—	(Disabled)	—	—

(Continued)

(Continued)

Address	Register abbreviation	Register name	R/W	Initial value
0FBC _H	BGR1	LIN-UART baud rate generator register 1	R/W	00000000 _B
0FBD _H	BGR0	LIN-UART baud rate generator register 0	R/W	00000000 _B
0FBE _H	PSSR0	UART/SIO dedicated baud rate generator prescaler select register ch. 0	R/W	00000000 _B
0FBF _H	BRSR0	UART/SIO dedicated baud rate generator baud rate setting register ch. 0	R/W	00000000 _B
0FC0 _H to 0FC2 _H	—	(Disabled)	—	—
0FC3 _H	AIDRL	A/D input disable register (lower)	R/W	00000000 _B
0FC4 _H to 0FE3 _H	—	(Disabled)	—	—
0FE4 _H	CRTH	Main CR clock trimming register (upper)	R/W	0XXXXXXXX _B
0FE5 _H	CRTL	Main CR clock trimming register (lower)	R/W	00XXXXXXXX _B
0FE6 _H , 0FE7 _H	—	(Disabled)	—	—
0FE8 _H	SYSC	System configuration register	R/W	11000001 _B
0FE9 _H	CMCR	Clock monitoring control register	R/W	00000000 _B
0FEA _H	CMDR	Clock monitoring data register	R	00000000 _B
0FEB _H	WDTH	Watchdog timer selection ID register (upper)	R	XXXXXXXX _B
0FEC _H	WDTL	Watchdog timer selection ID register (lower)	R	XXXXXXXX _B
0FED _H	—	(Disabled)	—	—
0FEE _H	ILSR	Input level select register	R/W	00000000 _B
0FEF _H to 0FFF _H	—	(Disabled)	—	—

• R/W access symbols

R/W : Readable / Writable

R : Read only

W : Write only

• Initial value symbols

0 : The initial value of this bit is "0".

1 : The initial value of this bit is "1".

X : The initial value of this bit is indeterminate.

Note: Do not write to an address that is "(Disabled)". If a "(Disabled)" address is read, an indeterminate value is returned.

MB95350L Series

■ INTERRUPT SOURCE TABLE

Interrupt source	Interrupt request number	Vector table address		Bit name of interrupt level setting register	Priority order of interrupt sources of the same level (occurring simultaneously)
		Upper	Lower		
External interrupt ch. 4	IRQ00	FFFA _H	FFFB _H	L00 [1:0]	High   Low
External interrupt ch. 5	IRQ01	FFF8 _H	FFF9 _H	L01 [1:0]	
External interrupt ch. 2	IRQ02	FFF6 _H	FFF7 _H	L02 [1:0]	
External interrupt ch. 6					
External interrupt ch. 3	IRQ03	FFF4 _H	FFF5 _H	L03 [1:0]	
External interrupt ch. 7					
LVD interrupt	IRQ04	FFF2 _H	FFF3 _H	L04 [1:0]	
UART/SIO ch. 0					
8/16-bit composite timer ch. 0 (lower)	IRQ05	FFF0 _H	FFF1 _H	L05 [1:0]	
8/16-bit composite timer ch. 0 (upper)	IRQ06	FFEE _H	FFEF _H	L06 [1:0]	
LIN-UART (reception)	IRQ07	FFEC _H	FFED _H	L07 [1:0]	
LIN-UART (transmission)	IRQ08	FFEA _H	FFEB _H	L08 [1:0]	
—	IRQ09	FFE8 _H	FFE9 _H	L09 [1:0]	
I ² C ch. 1	IRQ10	FFE6 _H	FFE7 _H	L10 [1:0]	
—	IRQ11	FFE4 _H	FFE5 _H	L11 [1:0]	
—	IRQ12	FFE2 _H	FFE3 _H	L12 [1:0]	
—	IRQ13	FFE0 _H	FFE1 _H	L13 [1:0]	
8/16-bit composite timer ch. 1 (upper)	IRQ14	FFDE _H	FFDF _H	L14 [1:0]	
—	IRQ15	FFDC _H	FFDD _H	L15 [1:0]	
I ² C ch. 0	IRQ16	FFDA _H	FFDB _H	L16 [1:0]	
—	IRQ17	FFD8 _H	FFD9 _H	L17 [1:0]	
8/10-bit A/D converter	IRQ18	FFD6 _H	FFD7 _H	L18 [1:0]	
Time-base timer	IRQ19	FFD4 _H	FFD5 _H	L19 [1:0]	
Watch prescaler	IRQ20	FFD2 _H	FFD3 _H	L20 [1:0]	
—	IRQ21	FFD0 _H	FFD1 _H	L21 [1:0]	
8/16-bit composite timer ch. 1 (lower)	IRQ22	FFCE _H	FFCF _H	L22 [1:0]	
Flash memory	IRQ23	FFCC _H	FFCD _H	L23 [1:0]	

■ ELECTRICAL CHARACTERISTICS

1. Absolute Maximum Ratings

Parameter	Symbol	Rating		Unit	Remarks
		Min	Max		
Power supply voltage*1	V_{CC}	$V_{SS} - 0.3$	$V_{SS} + 4.0$	V	
Input voltage*1	V_{I1}	$V_{SS} - 0.3$	$V_{SS} + 4.0$	V	Other than P14 and P15*2
	V_{I2}	$V_{SS} - 0.3$	$V_{SS} + 6.0$	V	P14 and P15*2
Output voltage*1	V_O	$V_{SS} - 0.3$	$V_{SS} + 4.0$	V	*2
Maximum clamp current	I_{CLAMP}	-2	+2	mA	Applicable to specific pins*3
Total maximum clamp current	$\sum I_{CLAMP} $	—	20	mA	Applicable to specific pins*3
“L” level maximum output current	I_{OL1}	—	15	mA	Other than P05, P06, P62 and P63
	I_{OL2}		15		P05, P06, P62 and P63
“L” level average current	I_{OLAV1}	—	4	mA	Other than P05, P06, P62 and P63 Average output current = operating current × operating ratio (1 pin)
	I_{OLAV2}		12		P05, P06, P62 and P63 Average output current = operating current × operating ratio (1 pin)
“L” level total maximum output current	$\sum I_{OL}$	—	100	mA	
“L” level total average output current	$\sum I_{OLAV}$	—	50	mA	Total average output current = operating current × operating ratio (Total number of pins)
“H” level maximum output current	I_{OH1}	—	-15	mA	Other than P05, P06, P62 and P63
	I_{OH2}		-15		P05, P06, P62 and P63
“H” level average current	I_{OHAV1}	—	-4	mA	Other than P05, P06, P62 and P63 Average output current = operating current × operating ratio (1 pin)
	I_{OHAV2}		-8		P05, P06, P62 and P63 Average output current = operating current × operating ratio (1 pin)
“H” level total maximum output current	$\sum I_{OH}$	—	-100	mA	
“H” level total average output current	$\sum I_{OHAV}$	—	-50	mA	Total average output current = operating current × operating ratio (Total number of pins)
Power consumption	P_d	—	320	mW	
Operating temperature	T_A	-40	+85	°C	
Storage temperature	T_{stg}	-55	+150	°C	

(Continued)

MB95350L Series

(Continued)

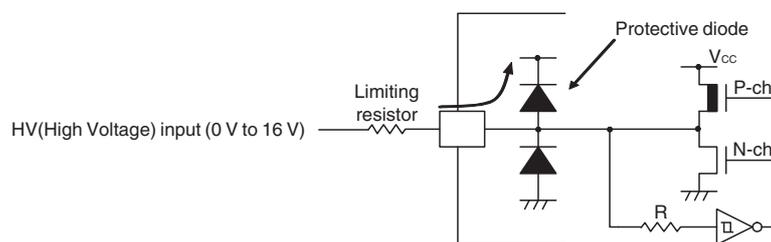
*1: The parameter is based on $V_{SS} = 0.0$ V.

*2: V_{I1} , V_{I2} and V_O must not exceed $V_{CC} + 0.3$ V. V_{I1} and V_{I2} must not exceed the rated voltage. However, if the maximum current to/from an input is limited by means of an external component, the I_{CLAMP} rating is used instead of the V_{I1} and V_{I2} ratings.

*3: Applicable to the following pins: P00 to P07, P15, P16, P62 to P64, PF0, PF1, PG0 to PG2

- Use under recommended operating conditions.
- Use with DC voltage (current).
- The HV (High Voltage) signal is an input signal exceeding the V_{CC} voltage. Always connect a limiting resistor between the HV (High Voltage) signal and the microcontroller before applying the HV (High Voltage) signal.
- The value of the limiting resistor should be set to a value at which the current to be input to the microcontroller pin when the HV (High Voltage) signal is input is below the standard value, irrespective of whether the current is transient current or stationary current.
- When the microcontroller drive current is low, such as in low power consumption modes, the HV (High Voltage) input potential may pass through the protective diode to increase the potential of the V_{CC} pin, affecting other devices.
- If the HV (High Voltage) signal is input when the microcontroller power supply is off (not fixed at 0 V), since power is supplied from the pins, incomplete operations may be executed.
- If the HV (High Voltage) input is input after power-on, since power is supplied from the pins, the voltage of power supply may not be sufficient to enable a power-on reset.
- Do not leave the HV (High Voltage) input pin unconnected.
- Example of a recommended circuit

- Input/Output equivalent circuit



WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

2. Recommended Operating Conditions

(V_{SS} = 0.0 V)

Parameter	Symbol	Value		Unit	Remarks	
		Min	Max			
Power supply voltage	V _{CC}	1.8*1*2*3	3.6	V	In normal operation, T _A = -10°C to +85°C	Other than on-chip debug mode
		2.0	3.6		In normal operation, T _A = -40°C to +85°C	
		1.5	3.6		Hold condition in stop mode	
		2.7	3.6		In normal operation	On-chip debug mode
		1.5	3.6		Hold condition in stop mode	
		Operating temperature	T _A		-40	+85
+5	+35			On-chip debug mode		

*1: This value varies depending on the operating frequency, the machine clock and the analog guaranteed range.

*2: This value is initially 2.03 V when the low-voltage detection reset is used.

*3: The threshold voltage can be set to 2.03 V, 2.55 V or 3.10 V by using the software.

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure. No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.

MB95350L Series

3. DC Characteristics

($V_{CC} = 2.7\text{ V to }3.6\text{ V}$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C to }+85^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min	Typ	Max		
"H" level input voltage	V_{IH1}	P04, P16, P17	*1	$0.7 V_{CC}$	—	$V_{CC} + 0.3$	V	When CMOS input level is selected
	V_{IH2}	P14, P15	*1	$0.7 V_{CC}$	—	$V_{SS} + 5.5$	V	When CMOS input level is selected
	V_{IHS1}	P00 to P07, P12, P16, P17, P60 to P64, PF0, PF1, PG0 to PG2	*1	$0.8 V_{CC}$	—	$V_{CC} + 0.3$	V	Hysteresis input
	V_{IHS2}	P14, P15	*1	$0.8 V_{CC}$	—	$V_{SS} + 5.5$	V	Hysteresis input
	V_{IHM}	PF2	—	$0.7 V_{CC}$	—	$V_{CC} + 0.3$	V	Hysteresis input
"L" level input voltage	V_{IL}	P04, P14 to P17	*1	$V_{SS} - 0.3$	—	$0.3 V_{CC}$	V	When CMOS input level is selected
	V_{ILS}	P00 to P07, P12, P14 to P17, P62 to P64, PF0, PF1, PG0 to PG2	*1	$V_{SS} - 0.3$	—	$0.2 V_{CC}$	V	Hysteresis input
	V_{ILM}	PF2	—	$V_{SS} - 0.3$	—	$0.3 V_{CC}$	V	Hysteresis input
Open-drain output application voltage	V_{D1}	P12	—	$V_{SS} - 0.3$	—	$V_{SS} + 5.5$	V	
	V_{D2}	P14, P15	—	$V_{SS} - 0.3$	—	$V_{SS} + 5.5$	V	
	V_{D3}	P16, P17	—	$V_{SS} - 0.3$	—	$V_{SS} + 3.6$	V	In I ² C mode
"H" level output voltage	V_{OH1}	Output pins other than P05, P06, P12, P62, P63	$I_{OH} = -4\text{ mA}$	$V_{CC} - 0.5$	—	—	V	
	V_{OH2}	P05, P06, P62 and P63	$I_{OH} = -8\text{ mA}$	$V_{CC} - 0.5$	—	—	V	
"L" level output voltage	V_{OL1}	Output pins other than P05, P06, P62, P63	$I_{OL} = 4\text{ mA}$	—	—	0.4	V	
	V_{OL2}	P05, P06, P62, P63	$I_{OL} = 12\text{ mA}$	—	—	0.4	V	
Input leak current (Hi-Z output leak current)	I_{LI}	All input pins	$0.0\text{ V} < V_I < V_{CC}$	-5	—	+5	μA	When pull-up resistance is disabled
Pull-up resistance	R_{PULL}	P00 to P07, PG1, PG2	$V_I = 0\text{ V}$	25	50	100	$\text{k}\Omega$	When pull-up resistance is enabled
Input capacitance	C_{IN}	Other than V_{CC} and V_{SS}	$f = 1\text{ MHz}$	—	5	15	pF	

(Continued)

MB95350L Series

($V_{CC} = 1.8\text{ V to }3.6\text{ V}$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C to }+85^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks	
				Min	Typ ³	Max			
Power supply current ^{*2}	I _{CC}	V _{CC} (External clock operation)	F _{CH} = 32 MHz F _{MP} = 16 MHz Main clock mode (divided by 2)	—	11.2	20	mA	Flash memory product (except writing and erasing)	
				—	26.2	38	mA	Flash memory product (at writing and erasing)	
				—	13.3	23.4	mA	At A/D conversion	
	I _{CCS}		F _{CH} = 32 MHz F _{MP} = 16 MHz Main sleep mode (divided by 2)	—	5.2	9.6	mA		
	I _{CCCL}		F _{CL} = 32 kHz F _{MPL} = 16 kHz Subclock mode (divided by 2) T _A = +25°C	—	15	35	μA		
	I _{CCCLS}		F _{CL} = 32 kHz F _{MPL} = 16 kHz Subsleep mode (divided by 2) T _A = +25°C	—	5	15	μA		
	I _{CCCT}		F _{CL} = 32 kHz Watch mode Main stop mode T _A = +25°C	—	1	10	μA		
	I _{CCMCR}		V _{CC}	F _{CRH} = 12.5 MHz F _{MP} = 12.5 MHz Main CR clock mode	—	9	15	mA	
	I _{CCSCR}			Sub-CR clock mode (divided by 2) T _A = +25°C	—	77	160	μA	
	I _{CCTS}		V _{CC} (External clock operation)	F _{CH} = 32 MHz Time-base timer mode	—	1.1	3	mA	
I _{CCCH}	Substop mode T _A = +25°C	—		0.1	5	μA			

(Continued)

MB95350L Series

(Continued)

($V_{CC} = 1.8 \text{ V to } 3.6 \text{ V}$, $V_{SS} = 0.0 \text{ V}$, $T_A = -40^\circ\text{C to } +85^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min	Typ ^{*3}	Max		
Power supply current ^{*2}	I_{LVD}	V_{CC}	Current consumption for low-voltage detection circuit only	—	6.4	32	μA	
	I_{CRH}		Current consumption for the main CR oscillator	—	0.25	0.6	mA	
	I_{CRL}		Current consumption for the sub-CR oscillator oscillating at 100 kHz	—	20	72	μA	

*1: The input levels of P04 and P14 to P17 can be switched between “CMOS input level” and “hysteresis input level”. The input level selection register (ILSR) is used to switch between the two input levels.

*2: • The power supply current is determined by the external clock. When the low-voltage detection option is selected, the power-supply current will be the sum of adding the current consumption of the low-voltage detection circuit (I_{LVD}) to one of the value from I_{CC} to I_{CCH} . In addition, when both the low-voltage detection option and the CR oscillator are selected, the power supply current will be the sum of adding up the current consumption of the low-voltage detection circuit, the current consumption of the CR oscillators (I_{CRH} , I_{CRL}) and a specified value. In on-chip debug mode, the CR oscillator (I_{CRH}) and the low-voltage detection circuit are always enabled, and current consumption therefore increases accordingly.

- See "4. AC Characteristics: (1) Clock Timing" for F_{CH} and F_{CL} .
- See "4. AC Characteristics: (2) Source Clock/Machine Clock" for F_{MP} and F_{MPL} .

*3: $V_{CC} = 3.0 \text{ V}$, $T_A = +25^\circ\text{C}$

4. AC Characteristics

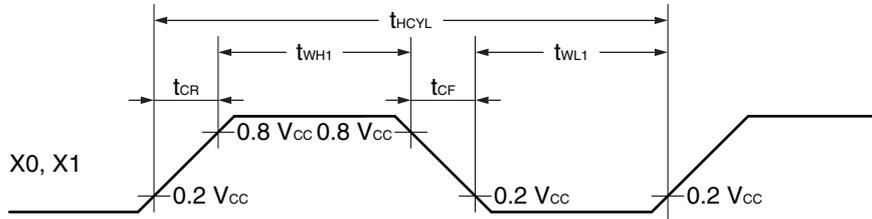
(1) Clock Timing

($V_{CC} = 1.8\text{ V to }3.6\text{ V}$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C to }+85^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks		
				Min	Typ	Max				
Clock frequency	F _{CH}	X0, X1	—	1	—	16.25	MHz	When the main oscillation circuit is used		
		X0	X1: open	1	—	12	MHz	When the main external clock is used		
		X0, X1	*	1	—	32.5	MHz			
	F _{CRH}	—	—	—	12.25	12.5	12.75	MHz	When the main CR clock is used $T_A = -10^\circ\text{C to }+85^\circ\text{C}$	
					9.8	10	10.2	MHz		
					7.84	8	8.16	MHz		
					0.98	1	1.02	MHz		
		—	—	—	—	12.1875	12.5	12.8125	MHz	When the main CR clock is used $T_A = -40^\circ\text{C to }-10^\circ\text{C}$
						9.75	10	10.25	MHz	
						7.8	8	8.2	MHz	
						0.975	1	1.025	MHz	
	F _{CL}	X0A, X1A	—	—	32.768	—	kHz	When the sub-oscillation circuit or the sub-external clock is used		
F _{CRL}	—	—	—	50	100	200	kHz	When the sub-CR clock is used		
Clock cycle time	t _{HCYL}	X0, X1	—	61.5	—	1000	ns	When the main oscillation circuit is used		
		X0	X1: open	83.4	—	1000	ns	When the main external clock is used		
		X0, X1	*	30.8	—	1000	ns			
	t _{LCYL}	X0A, X1A	—	—	30.5	—	μs	When the sub-oscillation circuit or the sub-external clock is used		
Input clock pulse width	t _{WH1}	X0	X1: open	33.4	—	—	ns	When the external clock is used, the duty ratio should range between 40% and 60%.		
	t _{WL1}	X0, X1	*	12.4	—	—	ns			
	t _{WH2} t _{WL2}	X0A	—	—	15.2	—	μs			
Input clock rise time and fall time	t _{CR}	X0	X1: open	—	—	5	ns	When the external clock is used		
	t _{CF}	X0, X1	*	—	—	5	ns			
CR oscillation start time	t _{CRHWK}	—	—	—	—	250	μs	When the main CR clock is used		
	t _{CRLWK}	—	—	—	—	10	μs	When the sub-CR clock is used		

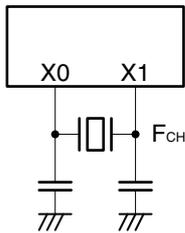
*: The external clock signal is input to X0 and the inverted external clock signal to X1.

- Input waveform generated when an external clock (main clock) is used

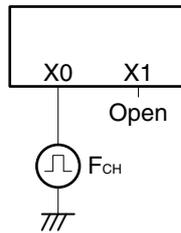


- Figure of main clock input port external connection

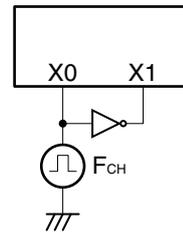
When a crystal oscillator or a ceramic oscillator is used



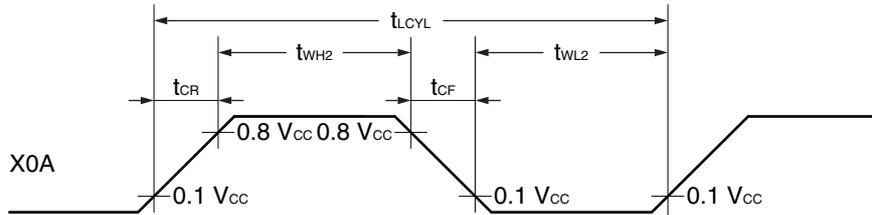
When the external clock is used (X1 is open)



When the external clock is used

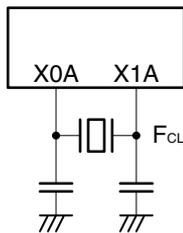


- Input waveform generated when an external clock (subclock) is used

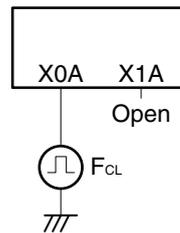


- Figure of subclock input port external connection

When a crystal oscillator or a ceramic oscillator is used



When the external clock is used



(2) Source Clock/Machine Clock

Parameter	Symbol	Pin name	Value			Unit	Remarks
			Min	Typ	Max		
Source clock cycle time*1	t _{SCLK}	—	61.5	—	2000	ns	When the main external clock is used Min: F _{CH} = 32.5 MHz, divided by 2 Max: F _{CH} = 1 MHz, divided by 2
			80	—	1000	ns	When the main CR clock is used Min: F _{CRH} = 12.5 MHz Max: F _{CRH} = 1 MHz
			—	61	—	μs	When the sub-oscillation clock is used F _{CL} = 32.768 kHz, divided by 2
			—	20	—	μs	When the sub-CR clock is used F _{CRL} = 100 kHz, divided by 2
Source clock frequency	F _{SP}	—	0.5	—	16.25	MHz	When the main oscillation clock is used
			1	—	12.5	MHz	When the main CR clock is used
	—		16.384	—	kHz	When the sub-oscillation clock is used	
	—		50	—	kHz	When the sub-CR clock is used F _{CRL} = 100 kHz, divided by 2	
Machine clock cycle time*2 (minimum instruction execution time)	t _{MCLK}	—	61.5	—	32000	ns	When the main oscillation clock is used Min: F _{SP} = 16.25 MHz, no division Max: F _{SP} = 0.5 MHz, divided by 16
			80	—	16000	ns	When the main CR clock is used Min: F _{SP} = 12.5 MHz Max: F _{SP} = 1 MHz, divided by 16
			61	—	976.5	μs	When the sub-oscillation clock is used Min: F _{SPL} = 16.384 kHz, no division Max: F _{SPL} = 16.384 kHz, divided by 16
			20	—	320	μs	When the sub-CR clock is used Min: F _{SPL} = 50 kHz, no division Max: F _{SPL} = 50 kHz, divided by 16
Machine clock frequency	F _{MP}	—	0.031	—	16.25	MHz	When the main oscillation clock is used
			0.0625	—	12.5	MHz	When the main CR clock is used
	1.024		—	16.384	kHz	When the sub-oscillation clock is used	
	3.125		—	50	kHz	When the sub-CR clock is used F _{CRL} = 100 kHz	

*1: This is the clock before it is divided according to the division ratio set by the machine clock division ratio selection bits (SYCC:DIV1, DIV0). This source clock is divided to become a machine clock according to the division ratio set by the machine clock division ratio selection bits (SYCC:DIV1, DIV0). In addition, a source clock can be selected from the following.

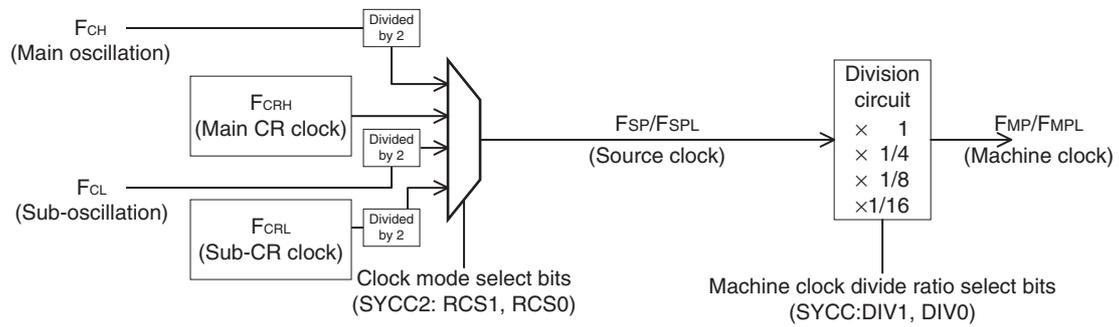
- Main clock divided by 2
- Main CR clock
- Subclock divided by 2
- Sub-CR clock divided by 2

*2: This is the operating clock of the microcontroller. A machine clock can be selected from the following.

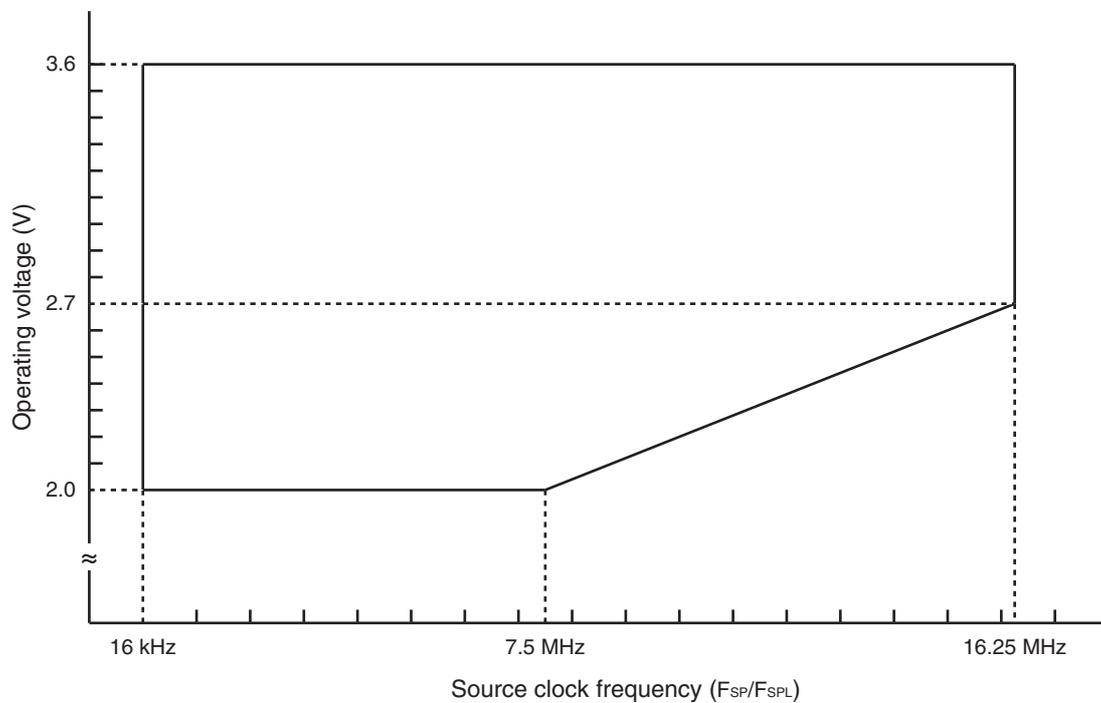
- Source clock (no division)
- Source clock divided by 4
- Source clock divided by 8
- Source clock divided by 16

MB95350L Series

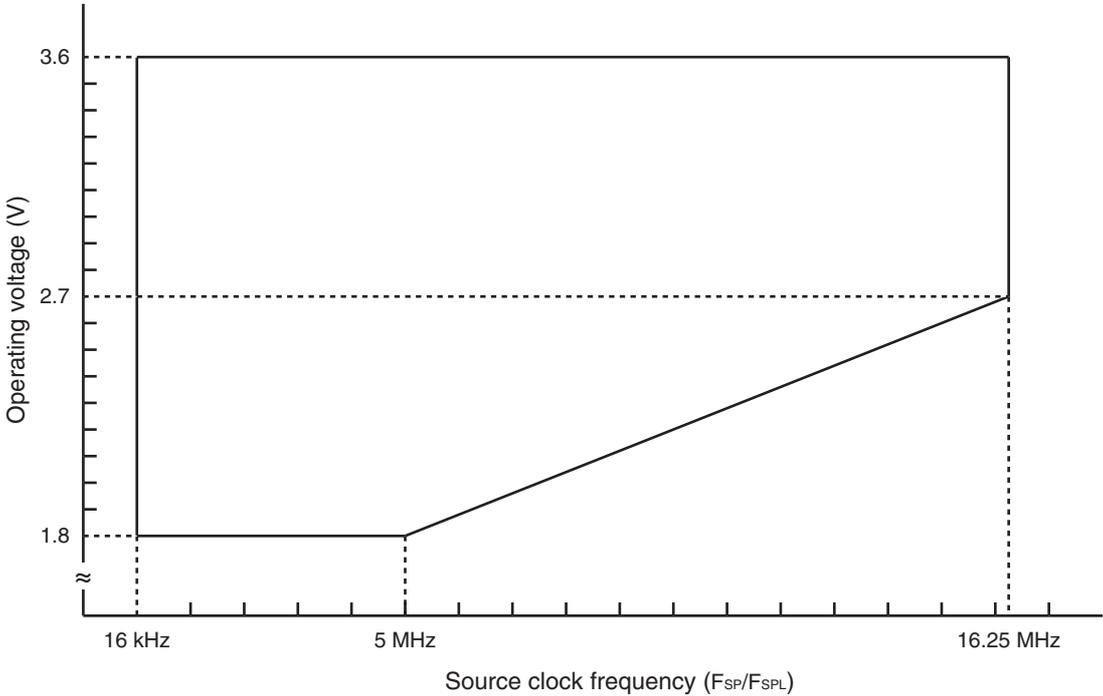
- Schematic diagram of the clock generation block



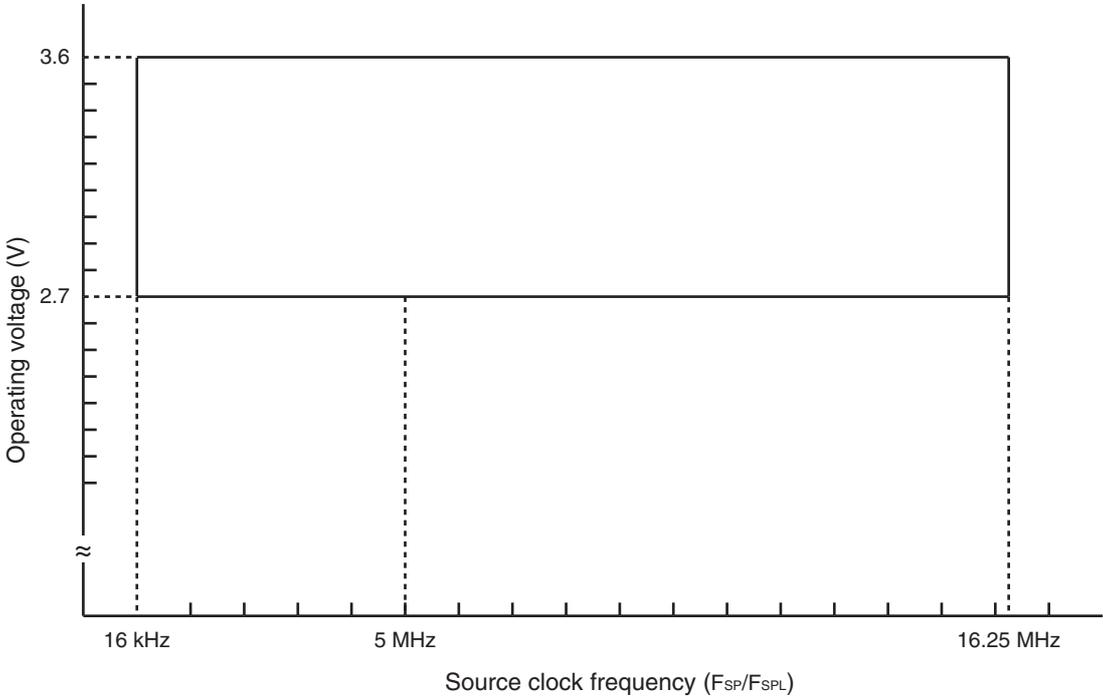
- Operating voltage - Operating frequency (When $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$)
Without the on-chip debug function



- Operating voltage - Operating frequency (When $T_A = -10^\circ\text{C}$ to $+85^\circ\text{C}$)
Without the on-chip debug function



- Operating voltage - Operating frequency (When $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$)
With the on-chip debug function



MB95350L Series

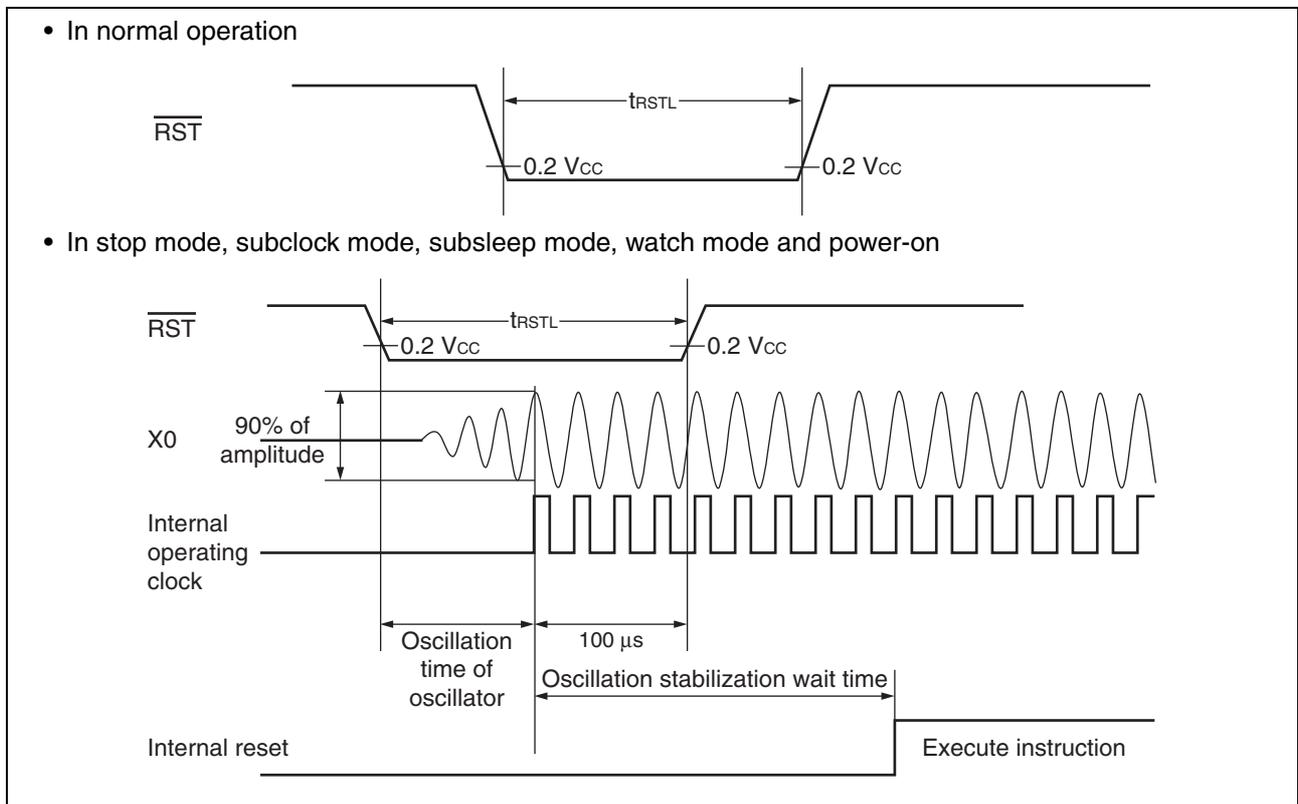
(3) External Reset

($V_{CC} = 3.0\text{ V to }3.6\text{ V}$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C to }+85^\circ\text{C}$)

Parameter	Symbol	Value		Unit	Remarks
		Min	Max		
$\overline{\text{RST}}$ "L" level pulse width	t_{RSTL}	$2 t_{\text{MCLK}}^{*1}$	—	ns	In normal operation
		Oscillation time of the oscillator ^{*2} + 100	—	μs	In stop mode, subclock mode, sub-sleep mode, watch mode, and power-on
		100	—	μs	In time-base timer mode

*1: See "(2) Source Clock/Machine Clock" for t_{MCLK} .

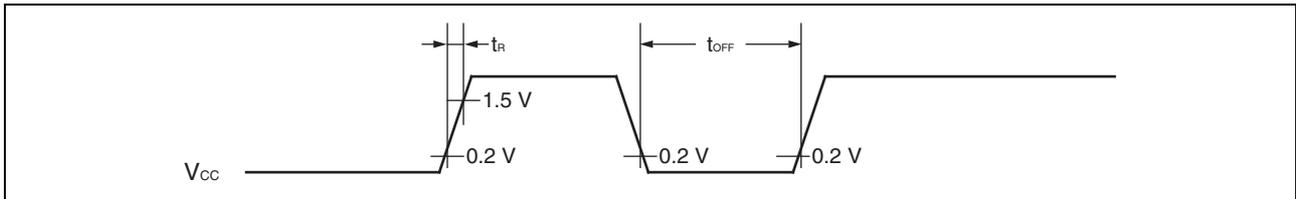
*2: The oscillation time of an oscillator is the time for it to reach 90% of its amplitude. The crystal oscillator has an oscillation time of between several ms and tens of ms. The ceramic oscillator has an oscillation time of between hundreds of μs and several ms. The external clock has an oscillation time of 0 ms. The CR oscillator clock has an oscillation time of between several μs and several ms.



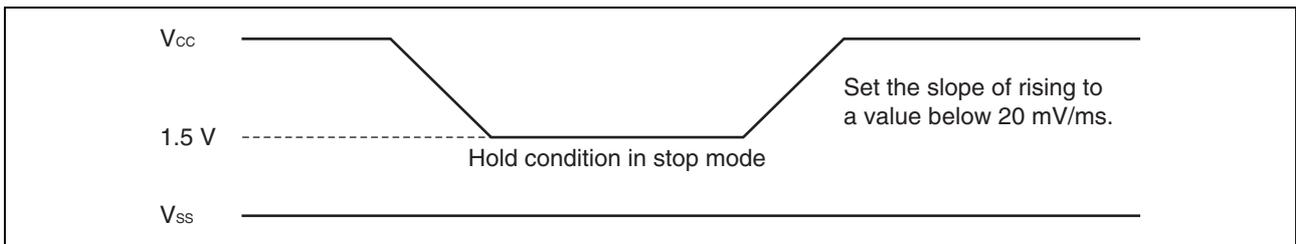
(4) Power-on Reset

($V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$)

Parameter	Symbol	Condition	Value		Unit	Remarks
			Min	Max		
Power supply rising time	t_R	—	—	50	ms	
Power supply cutoff time	t_{OFF}	—	1	—	ms	Wait time until power-on



Note: A sudden change of power supply voltage may activate the power-on reset function. When changing the power supply voltage during the operation, set the slope of rising to a value below within 20 mV/ms as shown below.



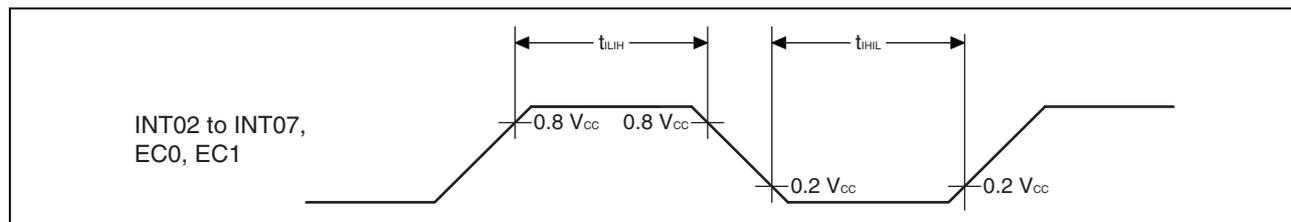
MB95350L Series

(5) Peripheral Input Timing

($V_{CC} = 3.0\text{ V to }3.6\text{ V}$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C to }+85^\circ\text{C}$)

Parameter	Symbol	Pin name	Value		Unit
			Min	Max	
Peripheral input "H" pulse width	t_{LH}	INT02 to INT07, EC0, EC1	$2 t_{MCLK}^*$	—	ns
Peripheral input "L" pulse width	t_{HL}		$2 t_{MCLK}^*$	—	ns

*: See "(2) Source Clock/Machine Clock" for t_{MCLK} .



(6) LIN-UART Timing

Sampling is executed at the rising edge of the sampling clock*¹, and serial clock delay is disabled*².
(ESCR register: SCES bit = 0, ECCR register: SCDE bit = 0)

(V_{CC} = 3.0 V to 3.6 V, V_{SS} = 0.0 V, T_A = -40°C to +85°C)

Parameter	Symbol	Pin name	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	t _{SCYC}	SCK	Internal clock operation output pin: C _L = 80 pF + 1 TTL	5 t _{MCLK} * ³	—	ns
SCK ↓ → SOT delay time	t _{SLOVI}	SCK, SOT		-95	+95	ns
Valid SIN → SCK ↑	t _{IVSHI}	SCK, SIN		t _{MCLK} * ³ + 190	—	ns
SCK ↑ → valid SIN hold time	t _{SHIXI}	SCK, SIN		0	—	ns
Serial clock “L” pulse width	t _{SLSH}	SCK	External clock operation output pin: C _L = 80 pF + 1 TTL	3 t _{MCLK} * ³ - t _R	—	ns
Serial clock “H” pulse width	t _{SHSL}	SCK		t _{MCLK} * ³ + 95	—	ns
SCK ↓ → SOT delay time	t _{SLOVE}	SCK, SOT		—	2 t _{MCLK} * ³ + 95	ns
Valid SIN → SCK ↑	t _{IVSHE}	SCK, SIN		190	—	ns
SCK ↑ → valid SIN hold time	t _{SHIXE}	SCK, SIN		t _{MCLK} * ³ + 95	—	ns
SCK fall time	t _F	SCK		—	10	ns
SCK rise time	t _R	SCK		—	10	ns

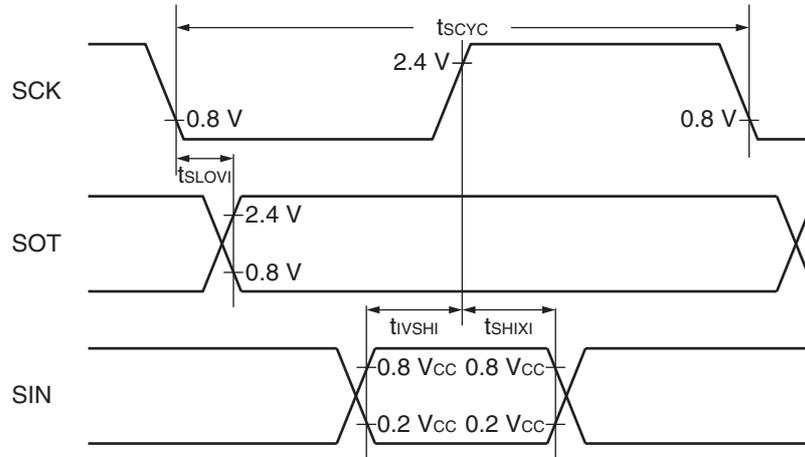
*1: There is a function used to choose whether the sampling of reception data is performed at a rising edge or a falling edge of the serial clock.

*2: The serial clock delay function is a function used to delay the output signal of the serial clock for half the clock.

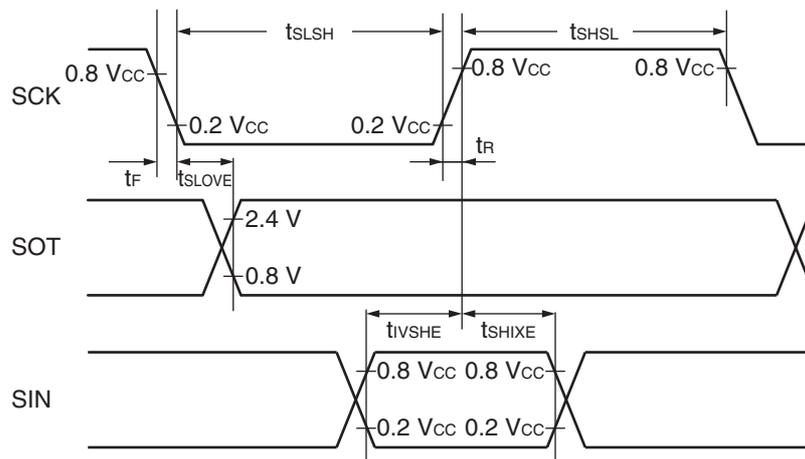
*3: See “(2) Source Clock/Machine Clock” for t_{MCLK}.

MB95350L Series

- Internal shift clock mode



- External shift clock mode



Sampling is executed at the falling edge of the sampling clock*¹, and serial clock delay is disabled*².
(ESCR register: SCES bit = 1, ECCR register: SCDE bit = 0)

(V_{CC} = 3.0 V to 3.6 V, V_{SS} = 0.0 V, T_A = -40°C to +85°C)

Parameter	Symbol	Pin name	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	t _{SCYC}	SCK	Internal clock operation output pin: C _L = 80 pF + 1 TTL	5 t _{MCLK} * ³	—	ns
SCK ↑ → SOT delay time	t _{SHOVI}	SCK, SOT		-95	+95	ns
Valid SIN → SCK ↓	t _{IVSLI}	SCK, SIN		t _{MCLK} * ³ + 190	—	ns
SCK ↓ → valid SIN hold time	t _{SLIXI}	SCK, SIN		0	—	ns
Serial clock "H" pulse width	t _{SHSL}	SCK	External clock operation output pin: C _L = 80 pF + 1 TTL	3 t _{MCLK} * ³ - t _R	—	ns
Serial clock "L" pulse width	t _{SLSH}	SCK		t _{MCLK} * ³ + 95	—	ns
SCK ↑ → SOT delay time	t _{SHOVE}	SCK, SOT		—	2 t _{MCLK} * ³ + 95	ns
Valid SIN → SCK ↓	t _{IVSLE}	SCK, SIN		190	—	ns
SCK ↓ → valid SIN hold time	t _{SLIXE}	SCK, SIN		t _{MCLK} * ³ + 95	—	ns
SCK fall time	t _F	SCK		—	10	ns
SCK rise time	t _R	SCK		—	10	ns

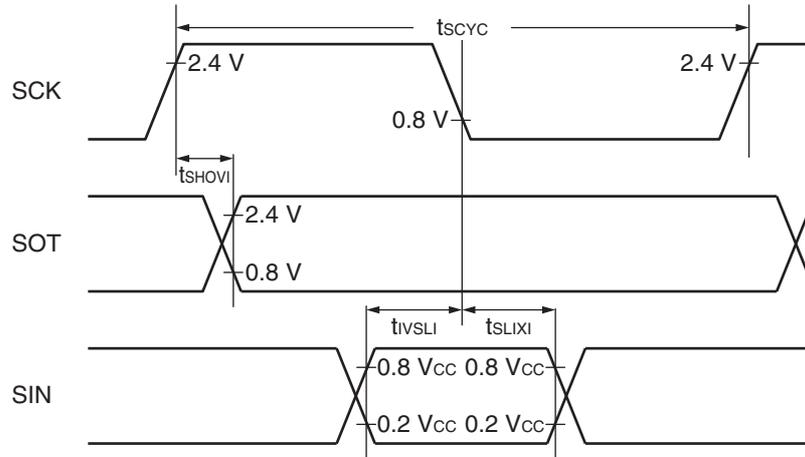
*1: There is a function used to choose whether the sampling of reception data is performed at a rising edge or a falling edge of the serial clock.

*2: The serial clock delay function is a function used to delay the output signal of the serial clock for half the clock.

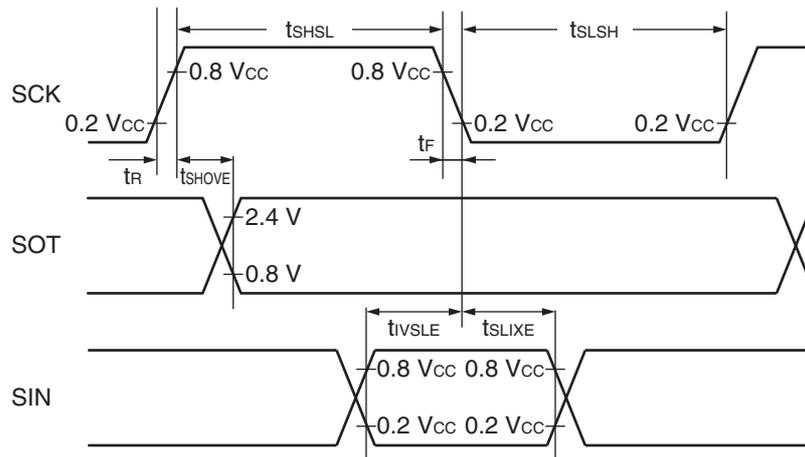
*3: See "(2) Source Clock/Machine Clock" for t_{MCLK}.

MB95350L Series

- Internal shift clock mode



- External shift clock mode



Sampling is executed at the rising edge of the sampling clock*¹, and serial clock delay is enabled*².
 (ESCR register: SCES bit = 0, ECCR register: SCDE bit = 1)

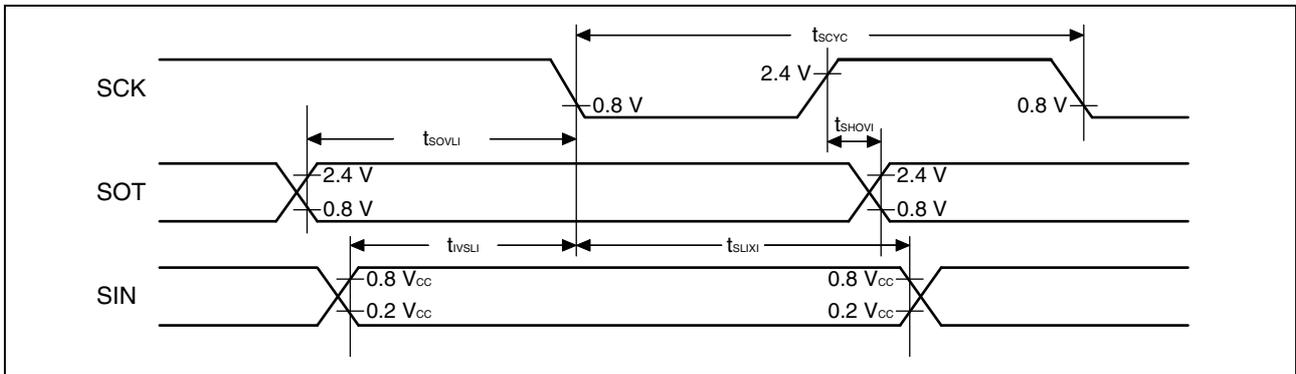
($V_{CC} = 3.0\text{ V to }3.6\text{ V}$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C to }+85^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	t_{SCYC}	SCK	Internal clock operation output pin: $C_L = 80\text{ pF} + 1\text{ TTL}$	$5 t_{MCLK}^{*3}$	—	ns
SCK \uparrow \rightarrow SOT delay time	t_{SHOVI}	SCK, SOT		-95	+95	ns
Valid SIN \rightarrow SCK \downarrow	t_{VSLI}	SCK, SIN		$t_{MCLK}^{*3} + 190$	—	ns
SCK \downarrow \rightarrow valid SIN hold time	t_{SLIXI}	SCK, SIN		0	—	ns
SOT \rightarrow SCK \downarrow delay time	t_{SOVLI}	SCK, SOT		—	$4 t_{MCLK}^{*3}$	ns

*1: There is a function used to choose whether the sampling of reception data is performed at a rising edge or a falling edge of the serial clock.

*2: The serial clock delay function is a function that delays the output signal of the serial clock for half clock.

*3: See “(2) Source Clock/Machine Clock” for t_{MCLK} .



MB95350L Series

Sampling is executed at the falling edge of the sampling clock*¹, and serial clock delay is enabled*².
 (ESCR register: SCES bit = 1, ECCR register: SCDE bit = 1)

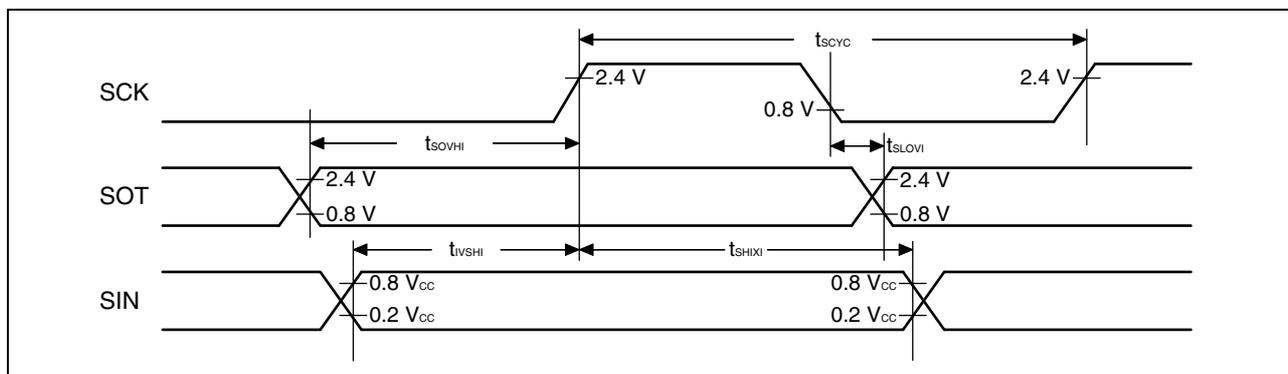
($V_{CC} = 3.0\text{ V to }3.6\text{ V}$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C to }+85^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	t_{SCYC}	SCK	Internal clock operation output pin: $C_L = 80\text{ pF} + 1\text{ TTL}$	$5 t_{MCLK}^{*3}$	—	ns
SCK ↓ → SOT delay time	t_{SLOVI}	SCK, SOT		-95	+95	ns
Valid SIN → SCK ↑	t_{VSHI}	SCK, SIN		$t_{MCLK}^{*3} + 190$	—	ns
SCK ↑ → valid SIN hold time	t_{SHIXI}	SCK, SIN		0	—	ns
SOT → SCK ↑ delay time	t_{SOVHI}	SCK, SOT		—	$4 t_{MCLK}^{*3}$	ns

*1: There is a function used to choose whether the sampling of reception data is performed at a rising edge or a falling edge of the serial clock.

*2: The serial clock delay function is a function that delays the output signal of the serial clock for half clock.

*3: See “(2) Source Clock/Machine Clock” for t_{MCLK} .



(7) Low-voltage Detection

($V_{SS} = 0.0\text{ V}$, $V_{CC} = 1.8\text{ V to }3.6\text{ V}$, $T_A = -40^\circ\text{C to }+85^\circ\text{C}$)

Parameter	Symbol	Value			Unit	Remarks
		Min	Typ	Max		
Power release voltage 0	V_{PDL0+}	1.83	1.93	2.03	V	At power supply rise
Power detection voltage 0	V_{PDL0-}	1.80	1.90	2.00	V	At power supply fall
Power release voltage 1	V_{PDL1+}	2.25	2.40	2.55	V	At power supply rise
Power detection voltage 1	V_{PDL1-}	2.20	2.35	2.50	V	At power supply fall
Power release voltage 2	V_{PDL2+}	2.80	2.95	3.10	V	At power supply rise
Power detection voltage 2	V_{PDL2-}	2.70	2.85	3.00	V	At power supply fall
Interrupt release voltage 0	V_{IDL0+}	2.03	2.18	2.33	V	At power supply rise
Interrupt detection voltage 0	V_{IDL0-}	2.00	2.15	2.30	V	At power supply fall
Interrupt release voltage 1	V_{IDL1+}	2.25	2.40	2.55	V	At power supply rise
Interrupt detection voltage 1	V_{IDL1-}	2.20	2.35	2.50	V	At power supply fall
Interrupt release voltage 2	V_{IDL2+}	2.46	2.61	2.76	V	At power supply rise
Interrupt detection voltage 2	V_{IDL2-}	2.40	2.55	2.70	V	At power supply fall
Interrupt release voltage 3	V_{IDL3+}	2.67	2.82	2.97	V	At power supply rise
Interrupt detection voltage 3	V_{IDL3-}	2.60	2.75	2.90	V	At power supply fall
Interrupt release voltage 4	V_{IDL4+}	2.90	3.10	3.30	V	At power supply rise
Interrupt detection voltage 4	V_{IDL4-}	2.80	3.00	3.20	V	At power supply fall
Power supply start voltage	V_{off}	—	—	1.8	V	
Power supply end voltage	V_{on}	3.3	—	—	V	
Power supply voltage change time (at power supply rise)	t_r	3000	—	—	μs	Slope of power supply that the reset release signal generates within the rating (V_{PDL+}/V_{IDL+})

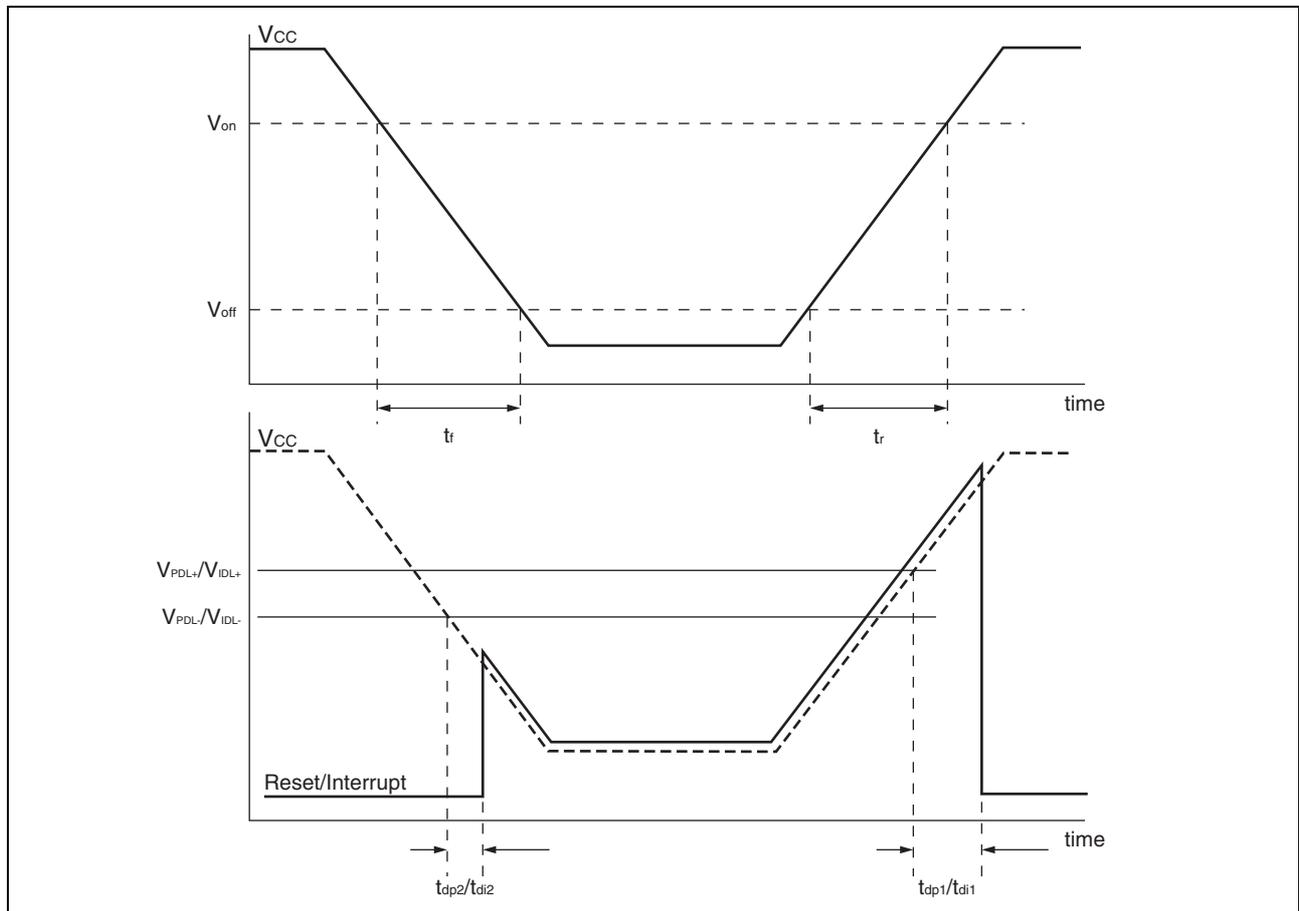
(Continued)

MB95350L Series

(Continued)

($V_{SS} = 0.0 \text{ V}$, $V_{CC} = 1.8 \text{ V to } 3.6 \text{ V}$, $T_A = -40^\circ\text{C to } +85^\circ\text{C}$)

Parameter	Symbol	Value			Unit	Remarks
		Min	Typ	Max		
Power supply voltage change time (at power supply fall)	t_r	3000	—	—	μs	Slope of power supply that the reset detection signal generates within the rating (V_{PDL}/V_{IDL})
Power reset release delay time	t_{dp1}	10	—	300	μs	
Power reset detection delay time	t_{dp2}	—	—	150	μs	
Interrupt reset release delay time	t_{di1}	10	—	200	μs	
Interrupt reset detection delay time	t_{di2}	—	—	150	μs	



(8) I²C Timing

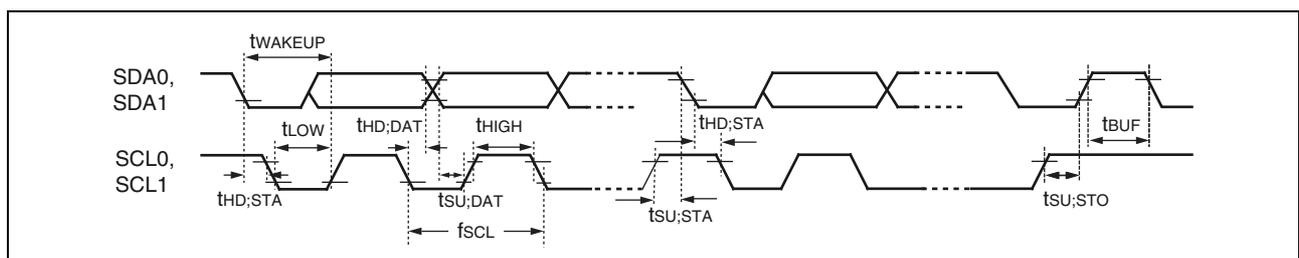
(V_{CC} = 3.0 V to 3.6 V, V_{SS} = 0.0 V, T_A = -40°C to +85°C)

Parameter	Symbol	Pin name	Condition	Value				Unit
				Standard-mode		Fast-mode		
				Min	Max	Min	Max	
SCL clock frequency	f _{SCL}	SCL0, SCL1		0	100	0	400	kHz
(Repeated) START condition hold time SDA ↓ → SCL ↓	t _{HD;STA}	SCL0, SCL1, SDA0, SDA1		4.0	—	0.6	—	μs
SCL clock "L" width	t _{LOW}	SCL0, SCL1		4.7	—	1.3	—	μs
SCL clock "H" width	t _{HIGH}	SCL0, SCL1		4.0	—	0.6	—	μs
(Repeated) START condition hold time SCL ↑ → SDA ↓	t _{SU;STA}	SCL0, SCL1, SDA0, SDA1		4.7	—	0.6	—	μs
Data hold time SCL ↓ → SDA ↓↑	t _{HD;DAT}	SCL0, SCL1, SDA0, SDA1	R = 1.7 kΩ, C = 50 pF*1	0	3.45*2	0	0.9*3	μs
Data setup time SDA ↓↑ → SCL ↑	t _{SU;DAT}	SCL0, SCL1, SDA0, SDA1		0.25	—	0.1	—	μs
STOP condition setup time SCL ↑ → SDA ↑	t _{SU;STO}	SCL0, SCL1, SDA0, SDA1		4	—	0.6	—	μs
Bus free time between STOP condition and START condition	t _{BUF}	SCL0, SCL1, SDA0, SDA1		4.7	—	1.3	—	μs

*1: R represents the pull-up resistor of the SCL0/1 and SDA0/1 lines, and C the load capacitor of the SCL0/1 and SDA0/1 lines.

*2: The maximum t_{HD;DAT} in the Standard-mode is applicable only when the time during which the device is holding the SCL signal at "L" (t_{LOW}) does not extend.

*3: A Fast-mode I²C-bus device can be used in a Standard-mode I²C-bus system, provided that the condition of t_{SU;DAT} ≥ 250 ns is fulfilled.



(Continued)

MB95350L Series

($V_{CC} = 3.0\text{ V to }3.6\text{ V}$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C to }+85^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value*2		Unit	Remarks
				Min	Max		
SCL clock "L" width	t_{LOW}	SCL0, SCL1	R = 1.7 k Ω , C = 50 pF*1	$(2 + nm/2)t_{MCLK} - 20$	—	ns	Master mode
SCL clock "H" width	t_{HIGH}	SCL0, SCL1		$(nm/2)t_{MCLK} - 20$	$(nm/2)t_{MCLK} + 20$	ns	Master mode
START condition hold time	$t_{HD,STA}$	SCL0, SCL1, SDA0, SDA1		$(-1 + nm/2)t_{MCLK} - 20$	$(-1 + nm)t_{MCLK} + 20$	ns	Master mode Maximum value is applied when $m, n = 1, 8$. Otherwise, the minimum value is applied.
STOP condition setup time	$t_{SU,STO}$	SCL0, SCL1, SDA0, SDA1		$(1 + nm/2)t_{MCLK} - 20$	$(1 + nm/2)t_{MCLK} + 20$	ns	Master mode
START condition setup time	$t_{SU,STA}$	SCL0, SCL1, SDA0, SDA1		$(1 + nm/2)t_{MCLK} - 20$	$(1 + nm/2)t_{MCLK} + 20$	ns	Master mode
Bus free time between STOP condition and START condition	t_{BUF}	SCL0, SCL1, SDA0, SDA1		$(2nm + 4)t_{MCLK} - 20$	—	ns	
Data hold time	$t_{HD,DAT}$	SCL0, SCL1, SDA0, SDA1		$3t_{MCLK} - 20$	—	ns	Master mode
Data setup time	$t_{SU,DAT}$	SCL0, SCL1, SDA0, SDA1		$(-2 + nm/2)t_{MCLK} - 20$	$(-1 + nm/2)t_{MCLK} + 20$	ns	Master mode When assuming that "L" of SCL is not extended, the minimum value is applied to first bit of continuous data. Otherwise, the maximum value is applied.
Setup time between clearing interrupt and SCL rising	$t_{SU,INT}$	SCL0, SCL1		$(nm/2)t_{MCLK} - 20$	$(1 + nm/2)t_{MCLK} + 20$	ns	Minimum value is applied to interrupt at 9th SCL \downarrow . Maximum value is applied to the interrupt at the 8th SCL \downarrow .

(Continued)

(Continued)

($V_{CC} = 3.0\text{ V to }3.6\text{ V}$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C to }+85^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value*2		Unit	Remarks
				Min	Max		
SCL clock "L" width	t_{LOW}	SCL0, SCL1	R = 1.7 k Ω , C = 50 pF*1	$4 t_{MCLK} - 20$	—	ns	At reception
SCL clock "H" width	t_{HIGH}	SCL0, SCL1		$4 t_{MCLK} - 20$	—	ns	At reception
START condition detection	$t_{HD;STA}$	SCL0, SCL1, SDA0, SDA1		$2 t_{MCLK} - 20$	—	ns	Undetected when 1 t_{MCLK} is used at reception
STOP condition detection	$t_{SU;STO}$	SCL0, SCL1, SDA0, SDA1		$2 t_{MCLK} - 20$	—	ns	Undetected when 1 t_{MCLK} is used at reception
RESTART condition detection condition	$t_{SU;STA}$	SCL0, SCL1, SDA0, SDA1		$2 t_{MCLK} - 20$	—	ns	Undetected when 1 t_{MCLK} is used at reception
Bus free time	t_{BUF}	SCL0, SCL1, SDA0, SDA1		$2 t_{MCLK} - 20$	—	ns	At reception
Data hold time	$t_{HD;DAT}$	SCL0, SCL1, SDA0, SDA1		$2 t_{MCLK} - 20$	—	ns	At slave transmission mode
Data setup time	$t_{SU;DAT}$	SCL0, SCL1, SDA0, SDA1		$t_{LOW} - 3 t_{MCLK} - 20$	—	ns	At slave transmission mode
Data hold time	$t_{HD;DAT}$	SCL0, SCL1, SDA0, SDA1		0	—	ns	At reception
Data setup time	$t_{SU;DAT}$	SCL0, SCL1, SDA0, SDA1		$t_{MCLK} - 20$	—	ns	At reception
SDA \downarrow \rightarrow SCL \uparrow (at wakeup function)	t_{WAKEUP}	SCL0, SCL1, SDA0, SDA1		Oscillation stabilization wait time $+2 t_{MCLK} - 20$	—	ns	

*1: R represents the pull-up resistor of the SCL0/1 and SDA0/1 lines, and C the load capacitor of the SCL0/1 and SDA0/1 lines.

*2: • See "(2) Source Clock/Machine Clock" for t_{MCLK} .

- m represents the CS4 bit and CS3 bit (bit4 and bit3) in the I²C clock control register (ICCR0).
- n represents the CS2 bit to CS0 bit (bit2 to bit0) in the I²C clock control register (ICCR0).
- The actual timing of I²C is determined by the values of m and n set by the machine clock (t_{MCLK}) and the CS4 to CS0 bits in the ICCR0 register.
- Standard-mode:
m and n can be set to values in the following range: $0.9\text{ MHz} < t_{MCLK}$ (machine clock) $< 10\text{ MHz}$.
The usable frequencies of the machine clock are determined by the settings of m and n as shown below.

(m, n) = (1, 8)	: $0.9\text{ MHz} < t_{MCLK} \leq 1\text{ MHz}$
(m, n) = (1, 22), (5, 4), (6, 4), (7, 4), (8, 4)	: $0.9\text{ MHz} < t_{MCLK} \leq 2\text{ MHz}$
(m, n) = (1, 38), (5, 8), (6, 8), (7, 8), (8, 8)	: $0.9\text{ MHz} < t_{MCLK} \leq 4\text{ MHz}$
(m, n) = (1, 98)	: $0.9\text{ MHz} < t_{MCLK} \leq 10\text{ MHz}$
- Fast-mode:
m and n can be set to values in the following range: $3.3\text{ MHz} < t_{MCLK}$ (machine clock) $< 10\text{ MHz}$.
The usable frequencies of the machine clock are determined by the settings of m and n as shown below.

(m, n) = (1, 8)	: $3.3\text{ MHz} < t_{MCLK} \leq 4\text{ MHz}$
(m, n) = (1, 22), (5, 4)	: $3.3\text{ MHz} < t_{MCLK} \leq 8\text{ MHz}$
(m, n) = (6, 4)	: $3.3\text{ MHz} < t_{MCLK} \leq 10\text{ MHz}$

MB95350L Series

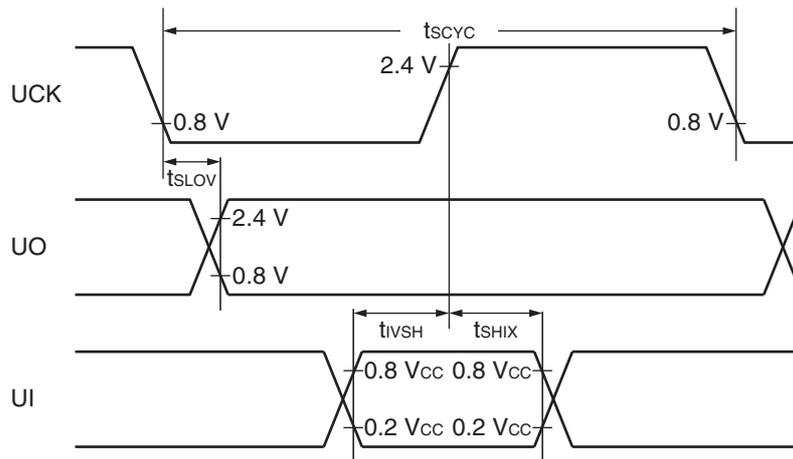
(9) UART/SIO, Serial I/O Timing

($V_{CC} = 3.0\text{ V to }3.6\text{ V}$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C to }+85^\circ\text{C}$)

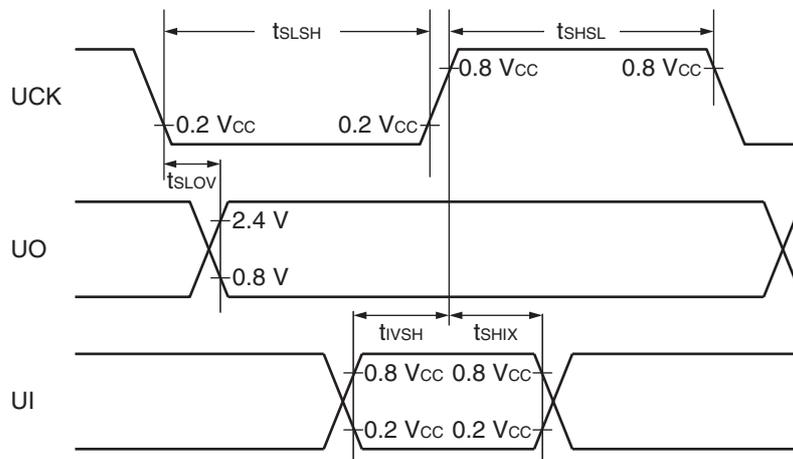
Parameter	Symbol	Pin name	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	t_{SCYC}	UCK	Internal clock operation	$4 t_{MCLK}^*$	—	ns
UCK ↓ → UO time	t_{SLOV}	UCK, UO		-190	+190	ns
Valid UI → UCK ↑	t_{IVSH}	UCK, UI		$2 t_{MCLK}^*$	—	ns
UCK ↑ → valid UI hold time	t_{SHIX}	UCK, UI		$2 t_{MCLK}^*$	—	ns
Serial clock “H” pulse width	t_{SHSL}	UCK	External clock operation	$4 t_{MCLK}^*$	—	ns
Serial clock “L” pulse width	t_{SLSH}	UCK		$4 t_{MCLK}^*$	—	ns
UCK ↓ → UO time	t_{SLOV}	UCK, UO		—	190	ns
Valid UI → UCK ↑	t_{IVSH}	UCK, UI		$2 t_{MCLK}^*$	—	ns
UCK ↑ → valid UI hold time	t_{SHIX}	UCK, UI	$2 t_{MCLK}^*$	—	ns	

*: See “(2) Source Clock/Machine Clock” for t_{MCLK} .

• Internal shift clock mode



• External shift clock mode



5. A/D Converter

(1) A/D Converter Electrical Characteristics

($V_{CC} = 1.8\text{ V to }3.6\text{ V}$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C to }+85^\circ\text{C}$)

Parameter	Symbol	Value			Unit	Remarks
		Min	Typ	Max		
Resolution	—	—	—	10	bit	
Total error		-3	—	+3	LSB	
Linearity error		-2.5	—	+2.5	LSB	
Differential linear error		-1.9	—	+1.9	LSB	
Zero transition voltage	V_{OT}	$V_{SS} - 1.5\text{ LSB}$	$V_{SS} + 0.5\text{ LSB}$	$V_{SS} + 2.5\text{ LSB}$	V	$2.7\text{ V} \leq V_{CC} \leq 3.6\text{ V}$
		$V_{SS} - 0.5\text{ LSB}$	$V_{SS} + 1.5\text{ LSB}$	$V_{SS} + 3.5\text{ LSB}$	V	$1.8\text{ V} \leq V_{CC} < 2.7\text{ V}$
Full-scale transition voltage	V_{FST}	$V_{CC} - 3.5\text{ LSB}$	$V_{CC} - 1.5\text{ LSB}$	$V_{CC} + 0.5\text{ LSB}$	V	$2.7\text{ V} \leq V_{CC} \leq 3.6\text{ V}$
		$V_{CC} - 2.5\text{ LSB}$	$V_{CC} - 0.5\text{ LSB}$	$V_{CC} + 1.5\text{ LSB}$	V	$1.8\text{ V} \leq V_{CC} < 2.7\text{ V}$
Compare time	—	1.3	—	140	μs	$2.7\text{ V} \leq V_{CC} \leq 3.6\text{ V}$
		20	—	140		$1.8\text{ V} \leq V_{CC} < 2.7\text{ V}$
Sampling time	—	0.4	—	—	μs	$2.7\text{ V} \leq V_{CC} \leq 3.6\text{ V}$, with external impedance $< 1.8\text{ k}\Omega$
		30	—	—	μs	$1.8\text{ V} \leq V_{CC} < 2.7\text{ V}$, with external impedance $< 14.8\text{ k}\Omega$
Analog input current	I_{AIN}	-0.3	—	+0.3	μA	
Analog input voltage	V_{AIN}	V_{SS}	—	V_{CC}	V	

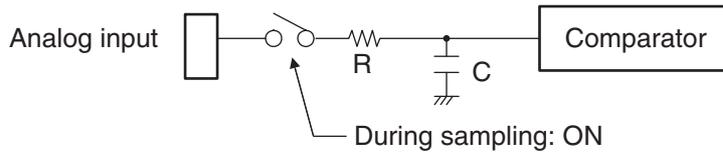
MB95350L Series

(2) Notes on Using the A/D Converter

• External impedance of analog input and its sampling time

- The A/D converter has a sample and hold circuit. If the external impedance is too high to keep sufficient sampling time, the analog voltage charged to the capacitor of the internal sample and hold circuit is insufficient, adversely affecting A/D conversion precision. Therefore, to satisfy the A/D conversion precision standard, considering the relationship between the external impedance and minimum sampling time, either adjust the register value and operating frequency or decrease the external impedance so that the sampling time is longer than the minimum value. In addition, if sufficient sampling time cannot be secured, connect a capacitor of about 0.1 μF to the analog input pin.

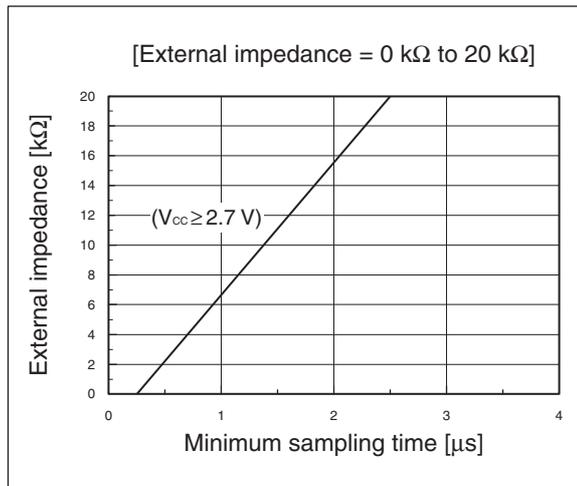
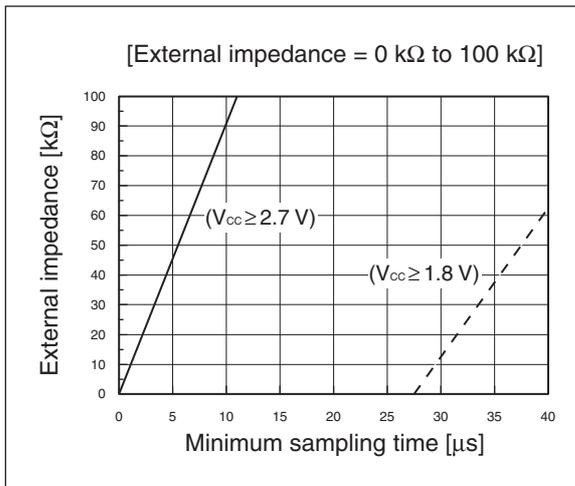
• Analog input equivalent circuit



V _{CC}	R	C
2.7 V \leq V _{CC} \leq 3.6 V	1.7 k Ω (Max)	14.5 pF (Max)
1.8 V \leq V _{CC} < 2.7 V	84 k Ω (Max)	25.2 pF (Max)

Note: The values are reference values.

• Relationship between external impedance and minimum sampling time

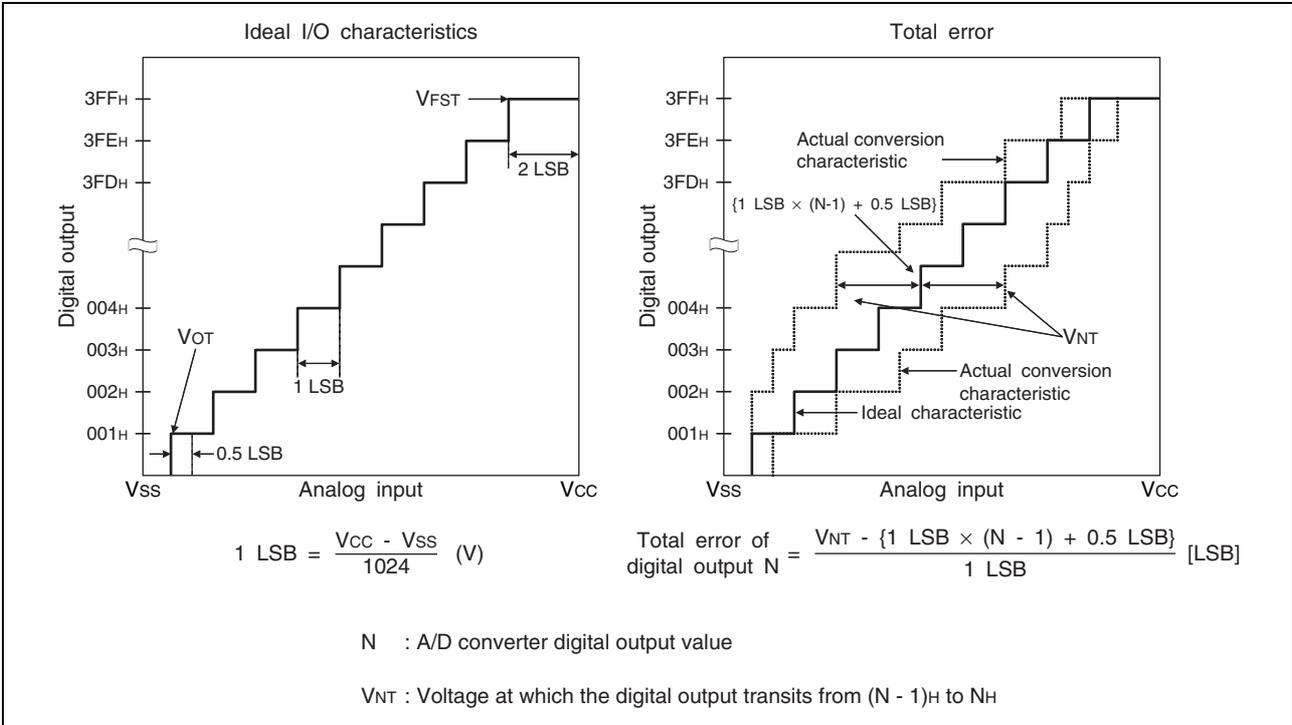


• A/D conversion error

As $V_{CC} - V_{SS1}$ decreases, the A/D conversion error increases proportionately.

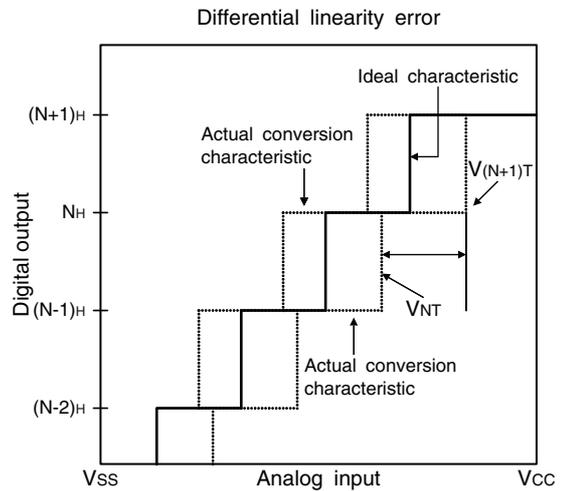
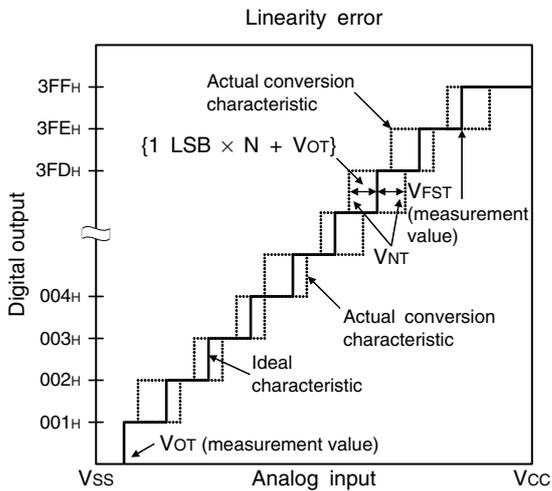
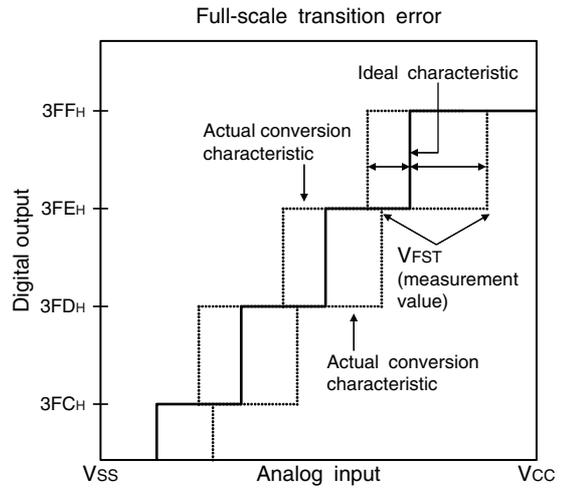
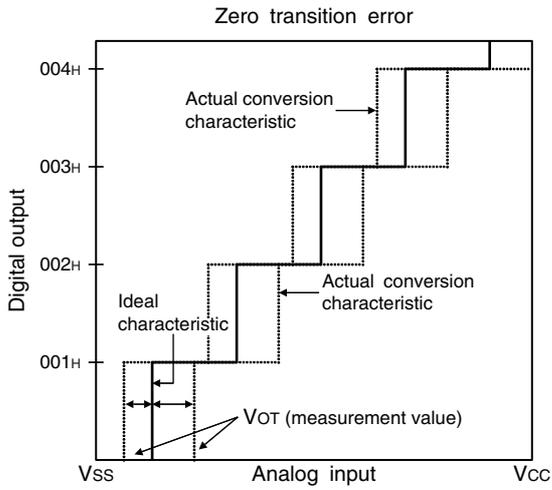
(3) Definitions of A/D Converter Terms

- Resolution
It indicates the level of analog variation that can be distinguished by the A/D converter. When the number of bits is 10, analog voltage can be divided into $2^{10} = 1024$.
- Linearity error (unit: LSB)
It indicates how much an actual conversion value deviates from the straight line connecting the zero transition point (“00 0000 0000” ← → “00 0000 0001”) of a device to the full-scale transition point (“11 1111 1111” ← → “11 1111 1110”) of the same device.
- Differential linear error (unit: LSB)
It indicates how much the input voltage required to change the output code by 1 LSB deviates from an ideal value.
- Total error (unit: LSB)
It indicates the difference between an actual value and a theoretical value. The error can be caused by a zero transition error, a full-scale transition errors, a linearity error, a quantum error, or noise.



(Continued)

(Continued)



$$\text{Linearity error of digital output } N = \frac{V_{NT} - \{1 \text{ LSB} \times N + \text{VOT}\}}{1 \text{ LSB}}$$

$$\text{Differential linear error of digital output } N = \frac{V_{(N+1)T} - V_{NT}}{1 \text{ LSB}} - 1$$

N : A/D converter digital output value

VNT : Voltage at which the digital output transits from (N - 1)H to NH

VOT (ideal value) = Vss + 0.5 LSB [V]

VFST (ideal value) = Vcc - 2 LSB [V]

6. Flash Memory Write/Erase Characteristics

Parameter	Value			Unit	Remarks
	Min	Typ	Max		
Sector erase time (2 Kbyte sector)	—	0.2* ¹	0.5* ²	s	The time of writing 00 _H prior to erasure is excluded.
Sector erase time (16 Kbyte sector)	—	0.5* ¹	7.5* ²	s	The time of writing 00 _H prior to erasure is excluded.
Byte writing time	—	21	6100* ²	μs	System-level overhead is excluded.
Erase/write cycle	100000	—	—	cycle	
Power supply voltage at erase/ write	2.7	3.0	3.6	V	
Flash memory data retention time	20* ³	—	—	year	Average T _A = +85°C

*1: T_A = +25°C, V_{CC} = 3.0 V, 100000 cycles

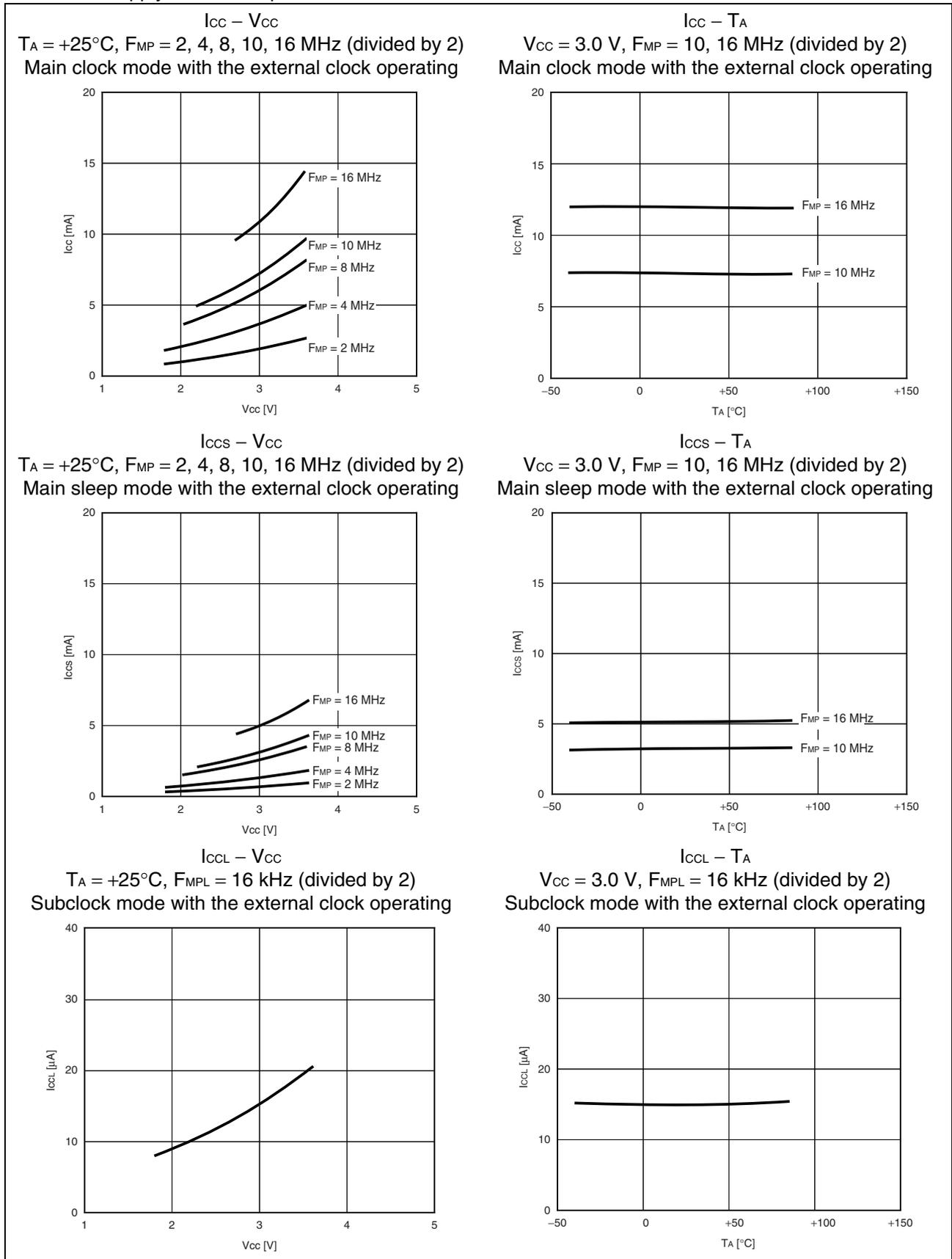
*2: T_A = +85°C, V_{CC} = 2.7 V, 100000 cycles

*3: This value is converted from the result of a technology reliability assessment. (The value is converted from the result of a high temperature accelerated test using the Arrhenius equation with the average temperature being +85°C).

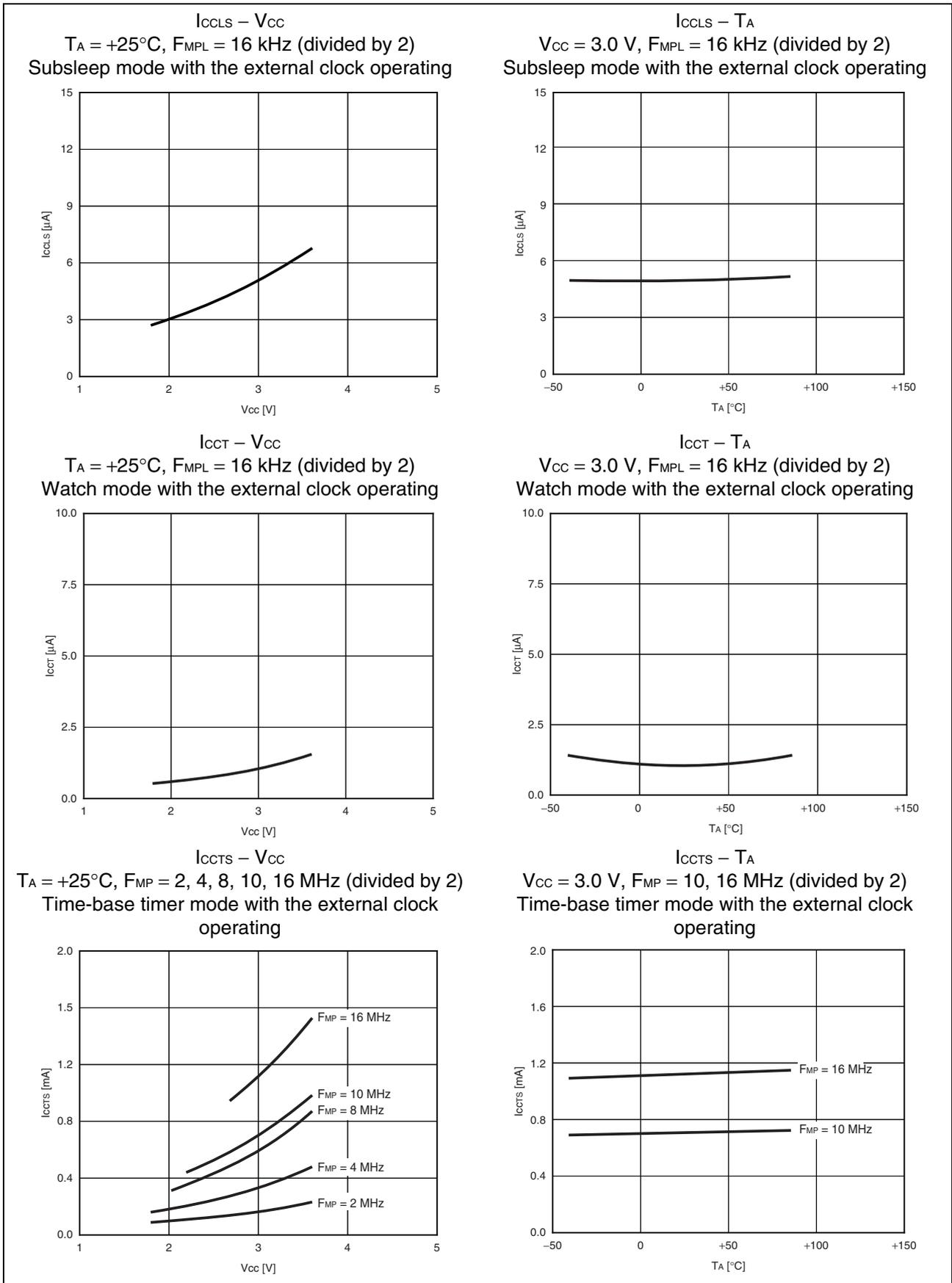
MB95350L Series

■ SAMPLE CHARACTERISTICS

- Power supply current temperature characteristics



(Continued)

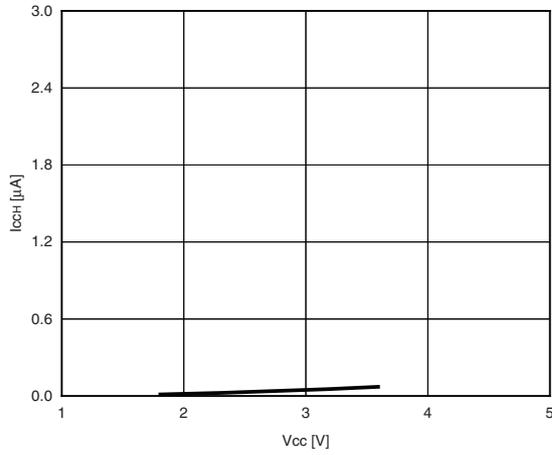


(Continued)

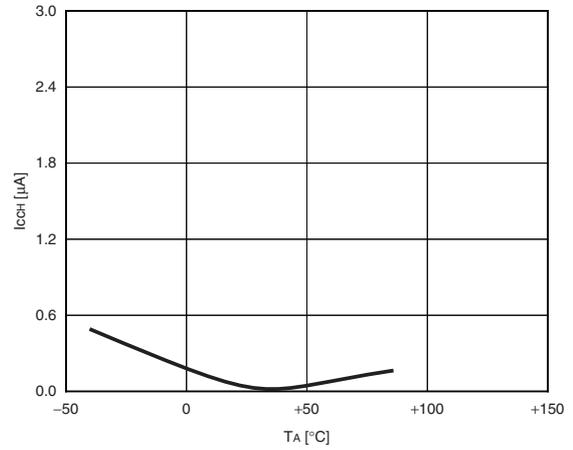
MB95350L Series

(Continued)

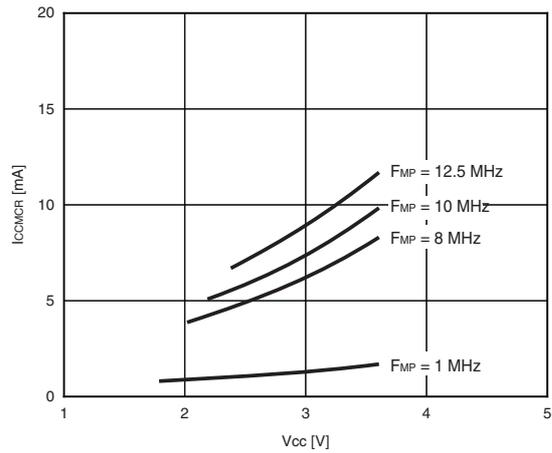
$I_{cch} - V_{CC}$
 $T_A = +25^\circ\text{C}$, $F_{MPL} = (\text{stop})$
 Substop mode with the external clock stopping



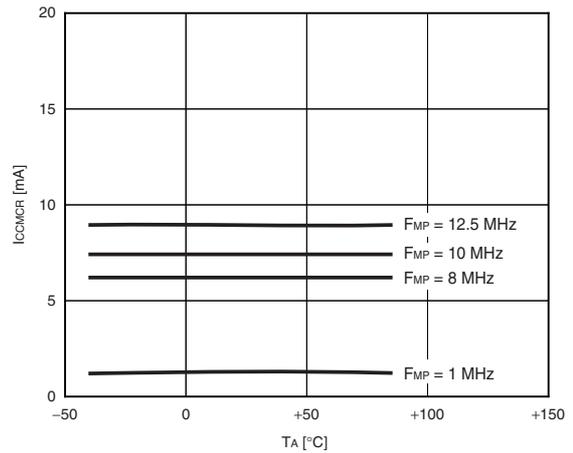
$I_{cch} - T_A$
 $V_{CC} = 3.0\text{ V}$, $F_{MPL} = (\text{stop})$
 Substop mode with the external clock stopping



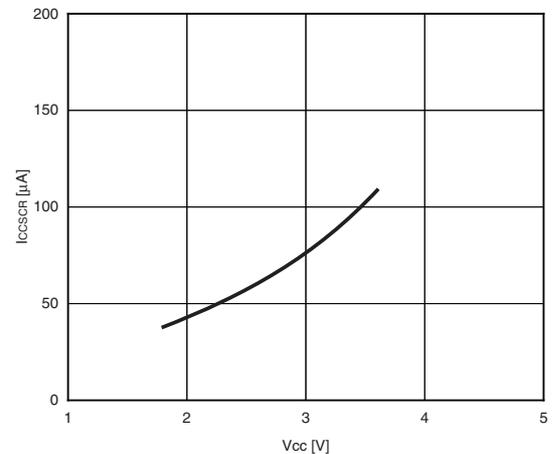
$I_{CCMCR} - V_{CC}$
 $T_A = +25^\circ\text{C}$, $F_{MP} = 1, 8, 10, 12.5\text{ MHz}$ (no division)
 Main clock mode with the main CR clock operating



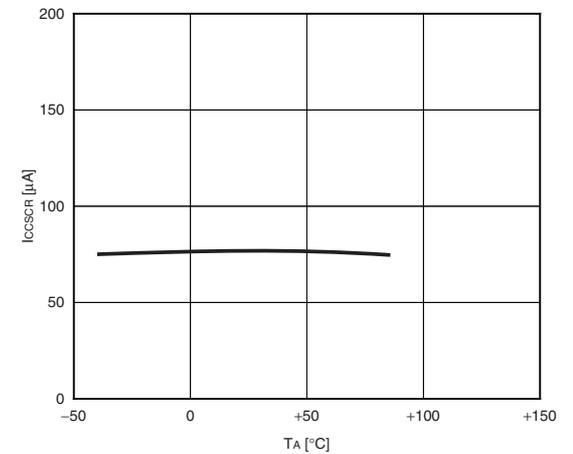
$I_{CCMCR} - T_A$
 $V_{CC} = 3.0\text{ V}$, $F_{MP} = 1, 8, 10, 12.5\text{ MHz}$ (no division)
 Main clock mode with the main CR clock operating



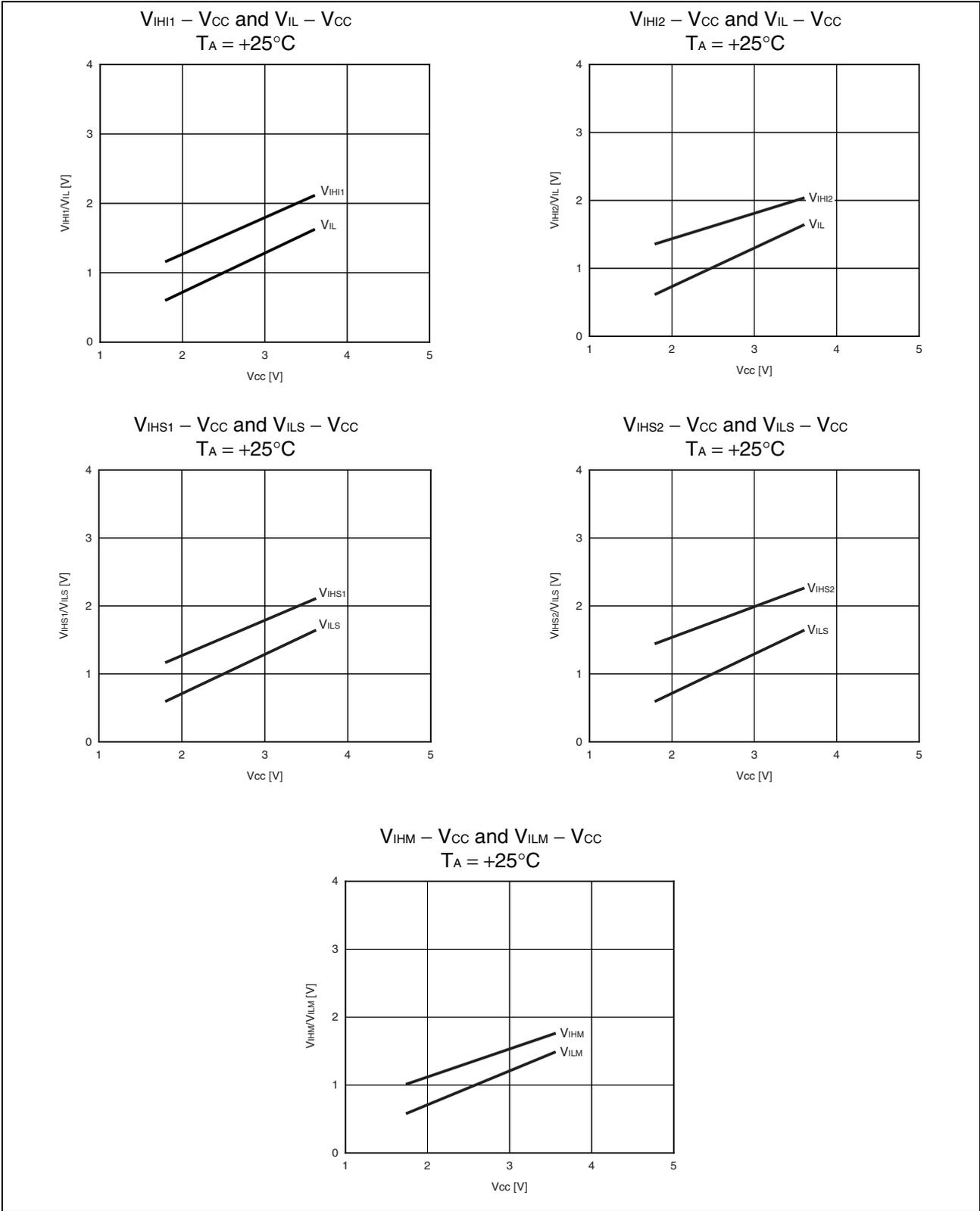
$I_{CCSCR} - V_{CC}$
 $T_A = +25^\circ\text{C}$, $F_{MPL} = 50\text{ kHz}$ (divided by 2)
 Subclock mode with the sub-CR clock operating



$I_{CCSCR} - T_A$
 $V_{CC} = 3.0\text{ V}$, $F_{MPL} = 50\text{ kHz}$ (divided by 2)
 Subclock mode with the sub-CR clock operating

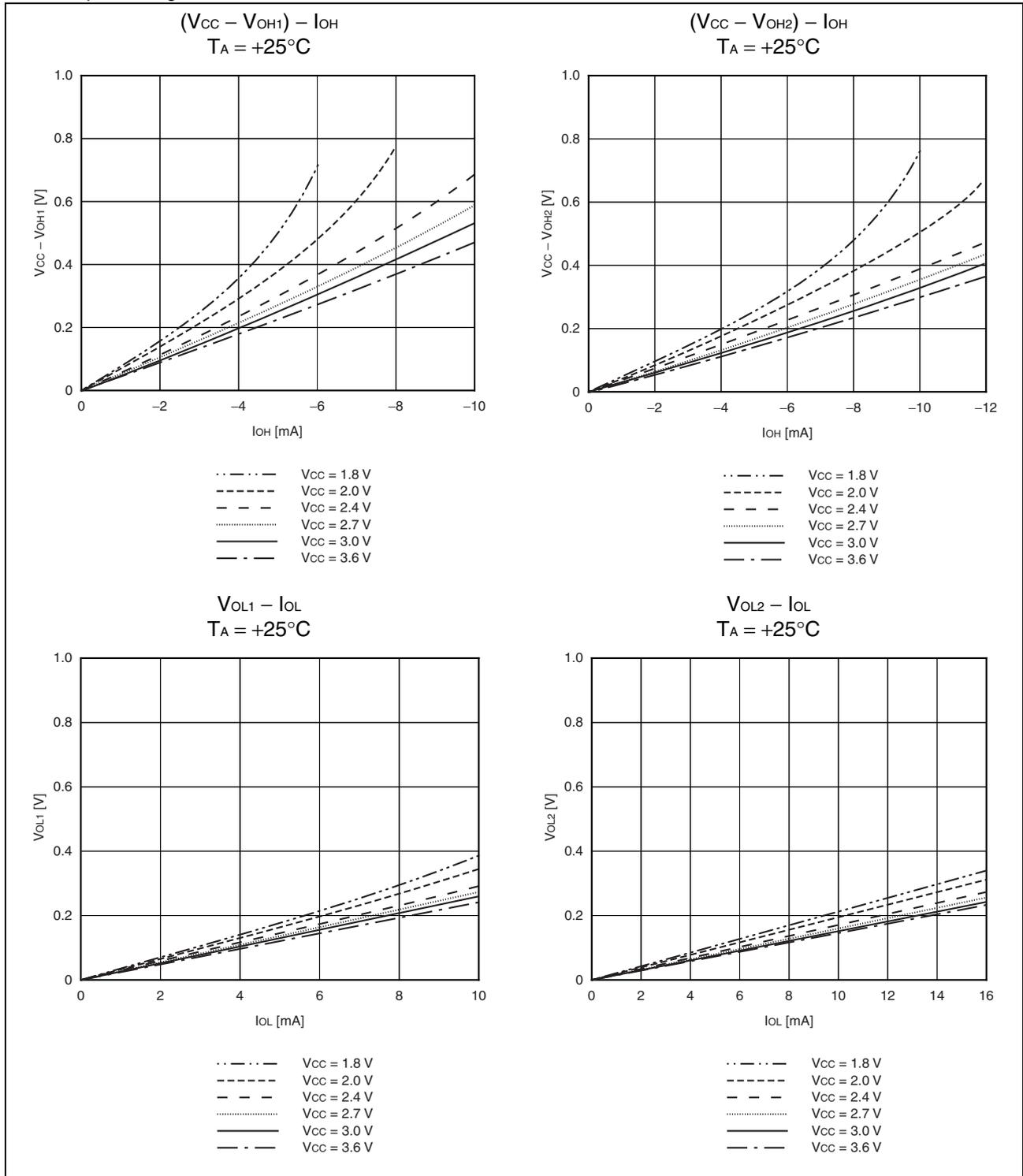


• Input voltage characteristics

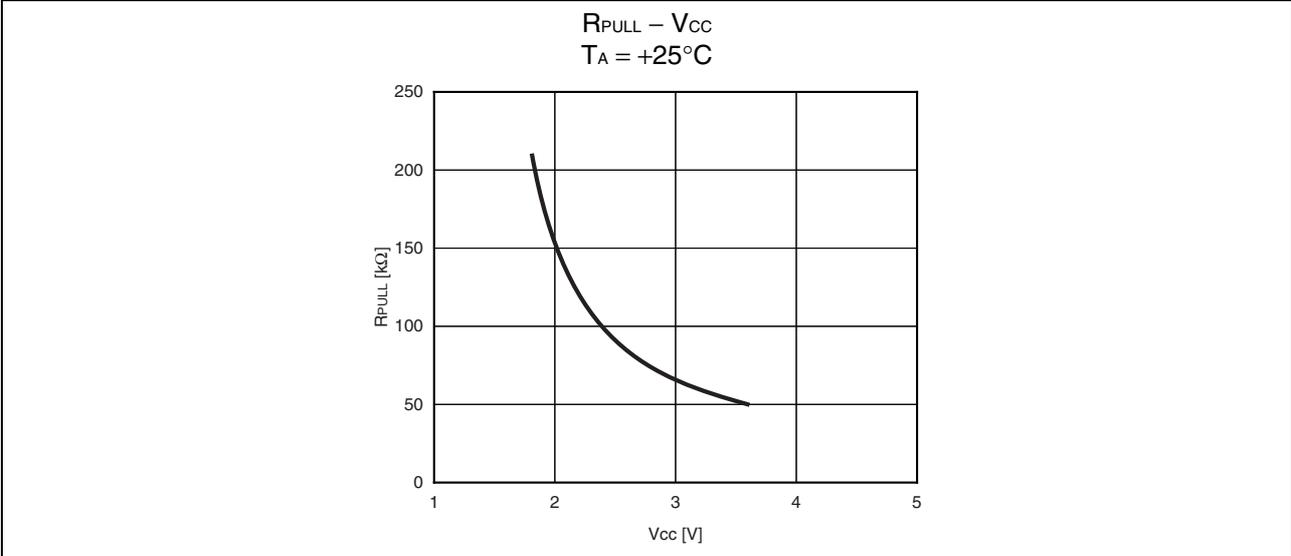


MB95350L Series

• Output voltage characteristics



- Pull-up characteristics



MB95350L Series

■ MASK OPTIONS

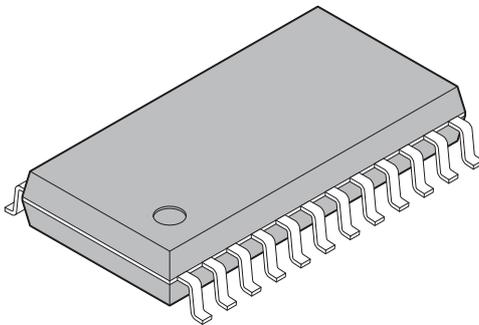
No.	Part Number	MB95F352E MB95F353E MB95F354E	MB95F352L MB95F353L MB95F354L
	Selectable/Fixed	Fixed	
1	Low-voltage detection reset	With low-voltage detection reset	Without low-voltage detection reset
2	Reset	Without dedicated reset input	With dedicated reset input

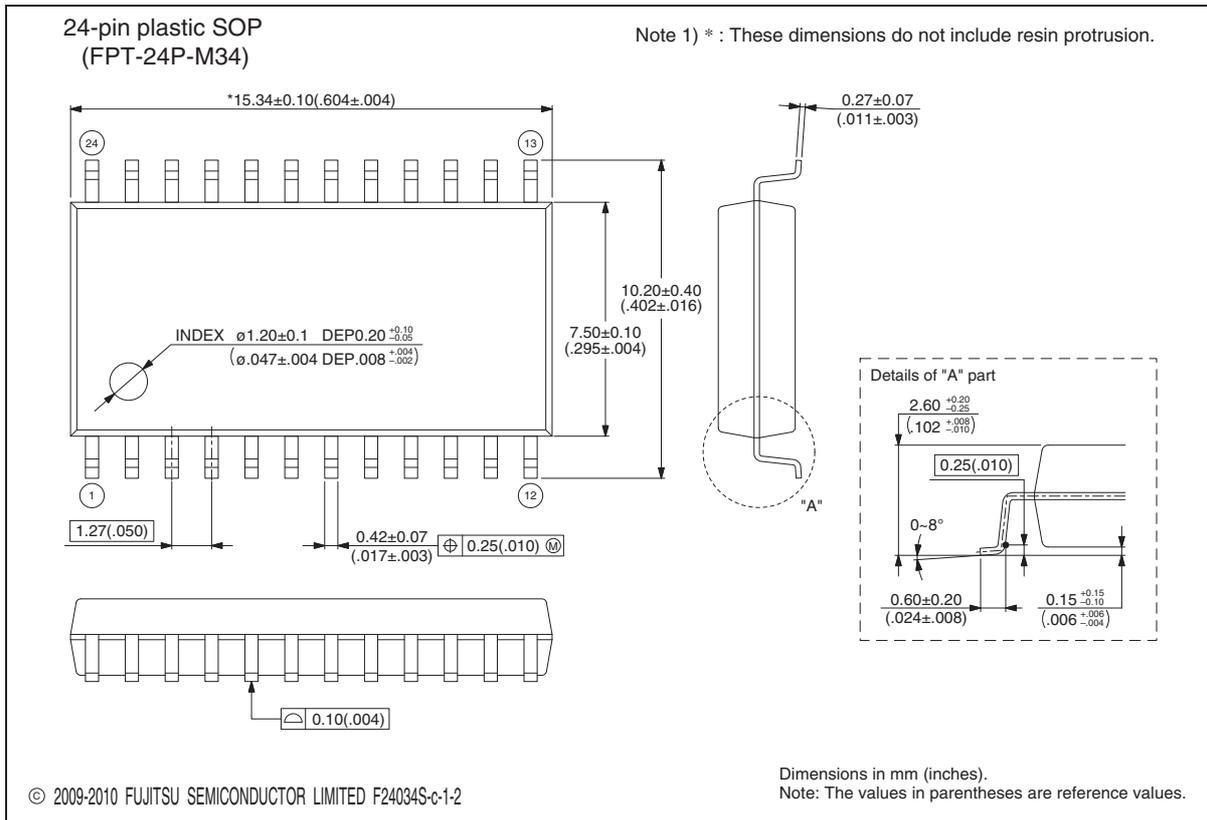
■ ORDERING INFORMATION

Part Number	Package
MB95F352EPF-G-SNE2 MB95F352LPF-G-SNE2 MB95F353EPF-G-SNE2 MB95F353LPF-G-SNE2 MB95F354EPF-G-SNE2 MB95F354LPF-G-SNE2	24-pin plastic SOP (FPT-24P-M34)
MB95F352EPFT-G-SNE2 MB95F352LPFT-G-SNE2 MB95F353EPFT-G-SNE2 MB95F353LPFT-G-SNE2 MB95F354EPFT-G-SNE2 MB95F354LPFT-G-SNE2	24-pin plastic TSSOP (FPT-24P-M10)
MB95F352EWQN-G-SNE1 MB95F352EWQN-G-SNERE1 MB95F352LWQN-G-SNE1 MB95F352LWQN-G-SNERE1 MB95F353EWQN-G-SNE1 MB95F353EWQN-G-SNERE1 MB95F353LWQN-G-SNE1 MB95F353LWQN-G-SNERE1 MB95F354EWQN-G-SNE1 MB95F354EWQN-G-SNERE1 MB95F354LWQN-G-SNE1 MB95F354LWQN-G-SNERE1	32-pin plastic QFN (LCC-32P-M19)

MB95350L Series

PACKAGE DIMENSION

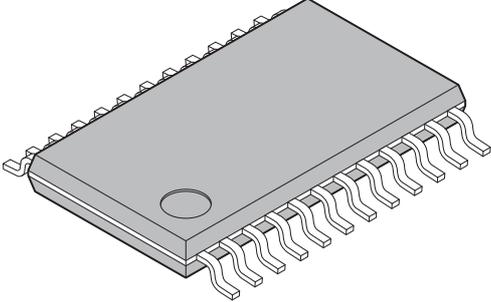
 <p>24-pin plastic SOP</p> <p>(FPT-24P-M34)</p>	Lead pitch	1.27 mm
	Package width × package length	7.50 mm × 15.34 mm
	Lead shape	Gullwing
	Lead bend direction	Normal bend
	Sealing method	Plastic mold
	Mounting height	2.80 mm MAX
	Weight	0.44 g

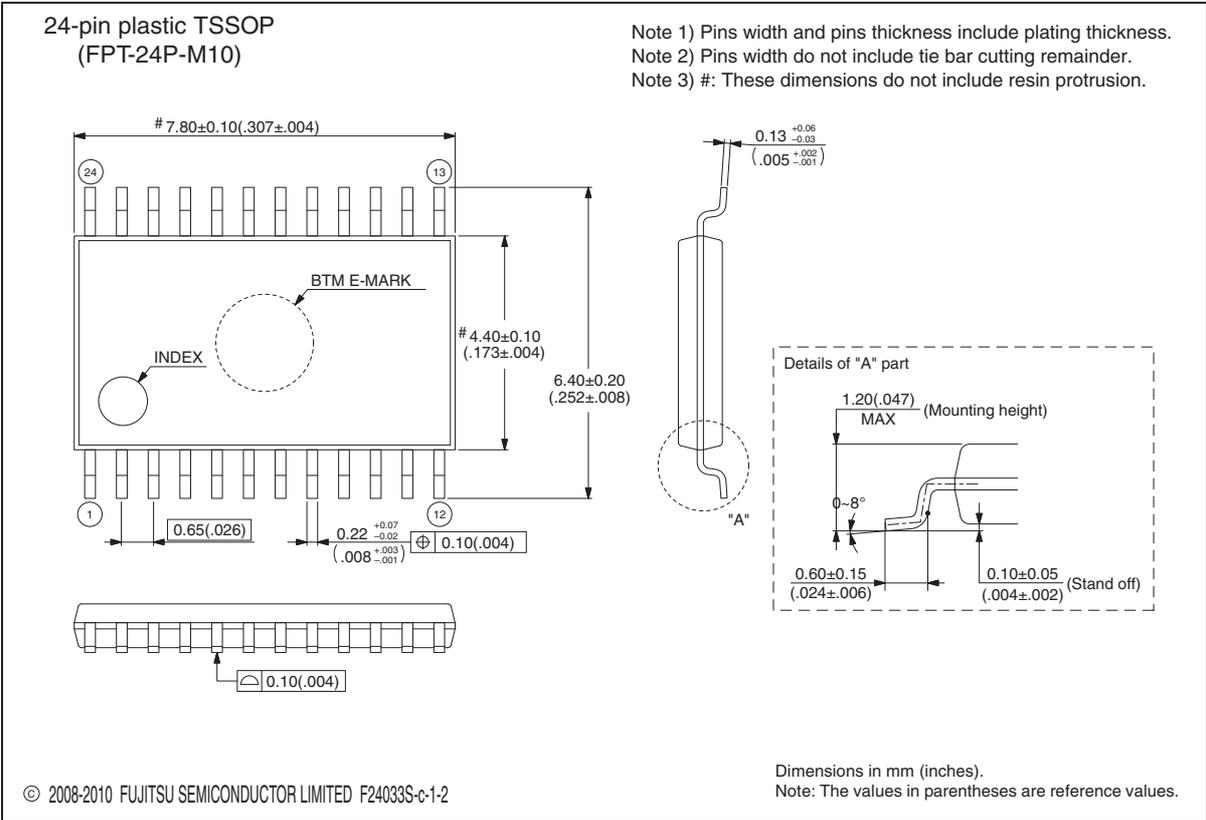


Please check the latest package dimension at the following URL.
<http://edevice.fujitsu.com/package/en-search/>

(Continued)

MB95350L Series

<p>24-pin plastic TSSOP</p>  <p>(FPT-24P-M10)</p>	Lead pitch	0.65 mm
	Package width × package length	4.40 mm × 7.80 mm
	Lead shape	Gullwing
	Sealing method	Plastic mold
	Mounting height	1.20 mm MAX
	Weight	0.10 g

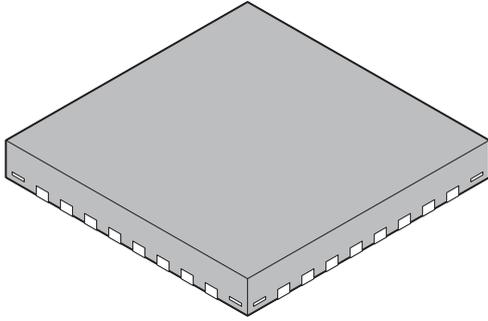


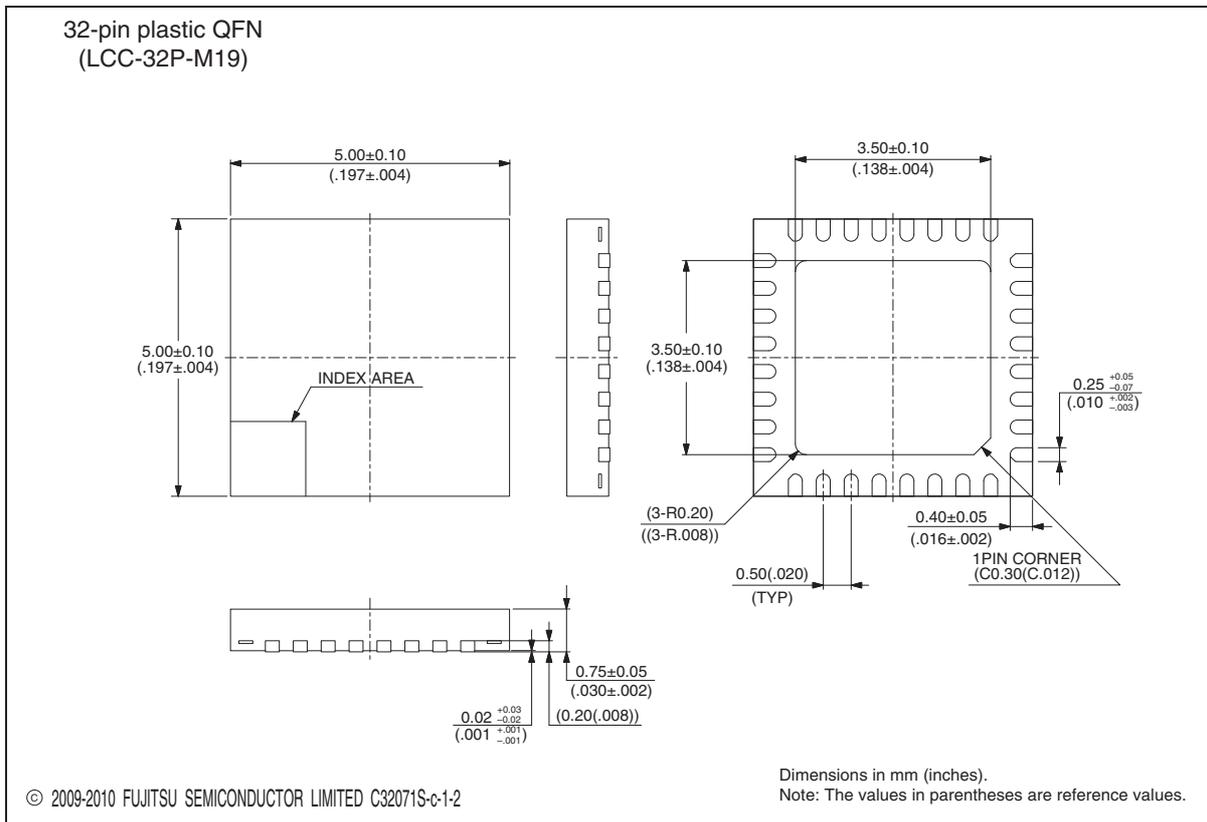
Please check the latest package dimension at the following URL.
<http://edevice.fujitsu.com/package/en-search/>

(Continued)

MB95350L Series

(Continued)

<p>32-pin plastic QFN</p>  <p>(LCC-32P-M19)</p>	Lead pitch	0.50 mm
	Package width × package length	5.00 mm × 5.00 mm
	Sealing method	Plastic mold
	Mounting height	0.80 mm MAX
	Weight	0.06 g



Please check the latest package dimension at the following URL.
<http://edevice.fujitsu.com/package/en-search/>

MAJOR CHANGES IN THIS EDITION

Page	Section	Details																																													
7	■ PIN ASSIGNMENT	Deleted the HCLK1 pin and the HCLK2 pin.																																													
9	■ PIN DESCRIPTION (24-pin MCU)	Deleted the HCLK1 pin and the HCLK2 pin.																																													
11	■ PIN DESCRIPTION (32-pin MCU)	Deleted the HCLK1 pin and the HCLK2 pin.																																													
16	■ BLOCK DIAGRAM	Deleted the HCLK1 pin and the HCLK2 pin.																																													
26	■ ELECTRICAL CHARACTERISTICS 3. DC Characteristics	Changed the value of V_{CC} in the operating conditions. 3.0 V to 3.6 V → 2.7 V to 3.6 V																																													
27		<p>Changed the value of V_{CC} in the operating conditions. 3.6 V → 1.8 V to 3.6 V</p> <p>Changed the typical (Typ) values and the maximum (Max) values of I_{CC}.</p> <table border="1" style="width: 100%; border-collapse: collapse; margin-bottom: 10px;"> <thead> <tr> <th colspan="3">Value</th> <th rowspan="2">Unit</th> <th rowspan="2">Remarks</th> </tr> <tr> <th>Min</th> <th>Typ</th> <th>Max</th> </tr> </thead> <tbody> <tr> <td style="text-align: center;">—</td> <td style="text-align: center;">13.6</td> <td style="text-align: center;">22.4</td> <td style="text-align: center;">mA</td> <td>Flash memory product (except writing and erasing)</td> </tr> <tr> <td style="text-align: center;">—</td> <td style="text-align: center;">38.1</td> <td style="text-align: center;">44.9</td> <td style="text-align: center;">mA</td> <td>Flash memory product (at writing and erasing)</td> </tr> <tr> <td style="text-align: center;">—</td> <td style="text-align: center;">15.1</td> <td style="text-align: center;">24.6</td> <td style="text-align: center;">mA</td> <td>At A/D conversion</td> </tr> </tbody> </table> <p style="text-align: center;">→</p> <table border="1" style="width: 100%; border-collapse: collapse; margin-bottom: 10px;"> <thead> <tr> <th colspan="3">Value</th> <th rowspan="2">Unit</th> <th rowspan="2">Remarks</th> </tr> <tr> <th>Min</th> <th>Typ*3</th> <th>Max</th> </tr> </thead> <tbody> <tr> <td style="text-align: center;">—</td> <td style="text-align: center;">11.2</td> <td style="text-align: center;">20</td> <td style="text-align: center;">mA</td> <td>Flash memory product (except writing and erasing)</td> </tr> <tr> <td style="text-align: center;">—</td> <td style="text-align: center;">26.2</td> <td style="text-align: center;">38</td> <td style="text-align: center;">mA</td> <td>Flash memory product (at writing and erasing)</td> </tr> <tr> <td style="text-align: center;">—</td> <td style="text-align: center;">13.3</td> <td style="text-align: center;">23.4</td> <td style="text-align: center;">mA</td> <td>At A/D conversion</td> </tr> </tbody> </table> <p>Changed the Typ value of I_{CCS}. 6.3 → 5.2</p> <p>Changed the Typ value and the Max value of I_{CCL}. Typ : 20 → 15 Max : 45 → 35</p> <p>Changed the Typ value and the Max value of I_{CCLs}. Typ : 6.3 → 5 Max : 30 → 15</p> <p>Changed the Typ value and the Max value of I_{CCT}. Typ : 2 → 1 Max : 22 → 10</p>	Value			Unit	Remarks	Min	Typ	Max	—	13.6	22.4	mA	Flash memory product (except writing and erasing)	—	38.1	44.9	mA	Flash memory product (at writing and erasing)	—	15.1	24.6	mA	At A/D conversion	Value			Unit	Remarks	Min	Typ*3	Max	—	11.2	20	mA	Flash memory product (except writing and erasing)	—	26.2	38	mA	Flash memory product (at writing and erasing)	—	13.3	23.4	mA
Value			Unit	Remarks																																											
Min	Typ	Max																																													
—	13.6	22.4	mA	Flash memory product (except writing and erasing)																																											
—	38.1	44.9	mA	Flash memory product (at writing and erasing)																																											
—	15.1	24.6	mA	At A/D conversion																																											
Value			Unit	Remarks																																											
Min	Typ*3	Max																																													
—	11.2	20	mA	Flash memory product (except writing and erasing)																																											
—	26.2	38	mA	Flash memory product (at writing and erasing)																																											
—	13.3	23.4	mA	At A/D conversion																																											

(Continued)

MB95350L Series

(Continued)

Page	Section	Details
27	■ ELECTRICAL CHARACTERISTICS 3. DC Characteristics	Changed the Typ value of I_{CCMCR} . 11 → 9 Changed the Typ value of I_{CCSCR} . 110 → 77 Changed the Typ value of I_{CCTS} . 1.8 → 1.1 Changed the Typ value of I_{CCH} . 1 → 0.1
28		Changed the Typ value of I_{LVD} . 8 → 6.4 Changed the Typ value of I_{CRH} . 0.5 → 0.25 Added the following note: *3: $V_{CC} = 3.0\text{ V}$, $T_A = +25^\circ\text{C}$
29	■ ELECTRICAL CHARACTERISTICS 4. AC Characteristics (1) Clock Timing	Deleted all information about the HCLK1 pin and the HCLK2 pin in the table.
30		Deleted HCLK1 and HCLK2 in the “• Input waveform generated when an external clock (main clock) is used”. Deleted the external connection diagram for the HCLK1 pin and HCLK2 pin in “• Figure of main clock input port external connection”.
43	■ ELECTRICAL CHARACTERISTICS 4. AC Characteristics (7) Low-voltage Detection	Deleted the following parameters: Power hysteresis width 0, Power hysteresis width 1, Power hysteresis width 2, Interrupt hysteresis width 0, Interrupt hysteresis width 1, Interrupt hysteresis width 2, Interrupt hysteresis width 3, Interrupt hysteresis width 4
44		Deleted V_{PHYS}/V_{IHYS} from the diagram.
54 to 59	■ SAMPLE CHARACTERISTICS	Added diagrams showing sample characteristics.
61	■ ORDERING INFORMATION	Added the following part numbers for the 32-pin plastic QFN package (LCC-32P-M19): MB95F352EWQN-G-SNE1 MB95F352LWQN-G-SNE1 MB95F353EWQN-G-SNE1 MB95F353LWQN-G-SNE1 MB95F354EWQN-G-SNE1 MB95F354LWQN-G-SNE1

The vertical lines marked on the left side of the page indicate the changes.

MEMO

MB95350L Series

FUJITSU SEMICONDUCTOR LIMITED

Nomura Fudosan Shin-yokohama Bldg. 10-23, Shin-yokohama 2-Chome,
Kohoku-ku Yokohama Kanagawa 222-0033, Japan
Tel: +81-45-415-5858
<http://jp.fujitsu.com/fsl/en/>

For further information please contact:

North and South America

FUJITSU SEMICONDUCTOR AMERICA, INC.
1250 E. Arques Avenue, M/S 333
Sunnyvale, CA 94085-5401, U.S.A.
Tel: +1-408-737-5600 Fax: +1-408-737-5999
<http://us.fujitsu.com/micro/>

Europe

FUJITSU SEMICONDUCTOR EUROPE GmbH
Pittlerstrasse 47, 63225 Langen, Germany
Tel: +49-6103-690-0 Fax: +49-6103-690-122
<http://emea.fujitsu.com/semiconductor/>

Korea

FUJITSU SEMICONDUCTOR KOREA LTD.
206 Kosmo Tower Building, 1002 Daechi-Dong,
Gangnam-Gu, Seoul 135-280, Republic of Korea
Tel: +82-2-3484-7100 Fax: +82-2-3484-7111
<http://kr.fujitsu.com/fmk/>

Asia Pacific

FUJITSU SEMICONDUCTOR ASIA PTE. LTD.
151 Lorong Chuan,
#05-08 New Tech Park 556741 Singapore
Tel : +65-6281-0770 Fax : +65-6281-0220
<http://www.fujitsu.com/sg/services/micro/semiconductor/>

FUJITSU SEMICONDUCTOR SHANGHAI CO., LTD.

Rm. 3102, Bund Center, No.222 Yan An Road (E),
Shanghai 200002, China
Tel : +86-21-6146-3688 Fax : +86-21-6335-1605
<http://cn.fujitsu.com/fmc/>

FUJITSU SEMICONDUCTOR PACIFIC ASIA LTD.

10/F., World Commerce Centre, 11 Canton Road,
Tsimshatsui, Kowloon, Hong Kong
Tel : +852-2377-0226 Fax : +852-2376-3269
<http://cn.fujitsu.com/fmc/en/>

Specifications are subject to change without notice. For further information please contact each office.

All Rights Reserved.

The contents of this document are subject to change without notice.

Customers are advised to consult with sales representatives before ordering.

The information, such as descriptions of function and application circuit examples, in this document are presented solely for the purpose of reference to show examples of operations and uses of FUJITSU SEMICONDUCTOR device; FUJITSU SEMICONDUCTOR does not warrant proper operation of the device with respect to use based on such information. When you develop equipment incorporating the device based on such information, you must assume any responsibility arising out of such use of the information.

FUJITSU SEMICONDUCTOR assumes no liability for any damages whatsoever arising out of the use of the information.

Any information in this document, including descriptions of function and schematic diagrams, shall not be construed as license of the use or exercise of any intellectual property right, such as patent right or copyright, or any other right of FUJITSU SEMICONDUCTOR or any third party or does FUJITSU SEMICONDUCTOR warrant non-infringement of any third-party's intellectual property right or other right by using such information. FUJITSU SEMICONDUCTOR assumes no liability for any infringement of the intellectual property rights or other rights of third parties which would result from the use of information contained herein.

The products described in this document are designed, developed and manufactured as contemplated for general use, including without limitation, ordinary industrial use, general office use, personal use, and household use, but are not designed, developed and manufactured as contemplated (1) for use accompanying fatal risks or dangers that, unless extremely high safety is secured, could have a serious effect to the public, and could lead directly to death, personal injury, severe physical damage or other loss (i.e., nuclear reaction control in nuclear facility, aircraft flight control, air traffic control, mass transport control, medical life support system, missile launch control in weapon system), or (2) for use requiring extremely high reliability (i.e., submersible repeater and artificial satellite).

Please note that FUJITSU SEMICONDUCTOR will not be liable against you and/or any third party for any claims or damages arising in connection with above-mentioned uses of the products.

Any semiconductor devices have an inherent chance of failure. You must protect against injury, damage or loss from such failures by incorporating safety design measures into your facility and equipment such as redundancy, fire protection, and prevention of over-current levels and other abnormal operating conditions.

Exportation/release of any products described in this document may require necessary procedures in accordance with the regulations of the Foreign Exchange and Foreign Trade Control Law of Japan and/or US export control laws.

The company names and brand names herein are the trademarks or registered trademarks of their respective owners.

Edited: Sales Promotion Department